

## Double channel high-side driver with analog current sense for automotive applications

Datasheet – production data

### Features

|                                   |            |                 |
|-----------------------------------|------------|-----------------|
| Max transient supply voltage      | $V_{CC}$   | 41V             |
| Operating voltage range           | $V_{CC}$   | 4.5 V to 28 V   |
| Typ on-state resistance (per ch.) | $R_{ON}$   | 25 m $\Omega$   |
| Current limitation (typ)          | $I_{LIMH}$ | 47 A            |
| Off state supply current          | $I_S$      | 2 $\mu A^{(1)}$ |

1. Typical value with all loads connected.

- General
  - Very low standby current
  - 3 V CMOS compatible inputs
  - Optimized electromagnetic emissions
  - Very low electromagnetic susceptibility
  - Compliance with European directive 2002/95/EC
  - Very low current sense leakage
- Diagnostic functions
  - Proportional load current sense
  - OFF-state open-load detection
  - Current sense disable
  - Thermal shutdown indication
  - Output short to  $V_{CC}$  detection
  - Over load and short to ground (power limitation) indication
- Protection
  - Undervoltage shutdown
  - Over voltage clamp
  - Load current limitation
  - Self limiting of fast thermal transients
  - Protection against loss of ground and loss of  $V_{CC}$
  - Over temperature shutdown with autorestart (thermal shutdown)
  - Reverse battery protection with self switch on of the Power MOSFET
  - Electrostatic discharge protection



- Inrush current active management by power limitation

### Applications

- All types of resistive, inductive and capacitive loads

### Description

The VND5E025AY-E is a double-channel high-side driver manufactured using STMicroelectronics® proprietary VIPower® M0-5 technology and housed in PowerSSO-36 package. The VND5E025AY-E is designed to drive 12 V automotive grounded loads, and to provide protection and diagnostics. It also implements a 3 V and 5 V CMOS-compatible interface for use with any microcontroller.

The device integrates advanced protective functions such as load current limitation, inrush and overload active management by power limitation, overtemperature shut-off with auto-restart and overvoltage active clamp.

A dedicated analog current sense pin is associated with every output channel providing enhanced diagnostic functions including fast detection of overload and short-circuit to ground through power limitation indication, overtemperature indication, short-circuit to  $V_{CC}$  diagnosis.

The current sensing and diagnostic feedback of the whole device can be disabled by pulling the CS\_DIS pin high to share the external sense resistor with similar devices.

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# 1 Block diagram and pin description

Figure 1. Block diagram

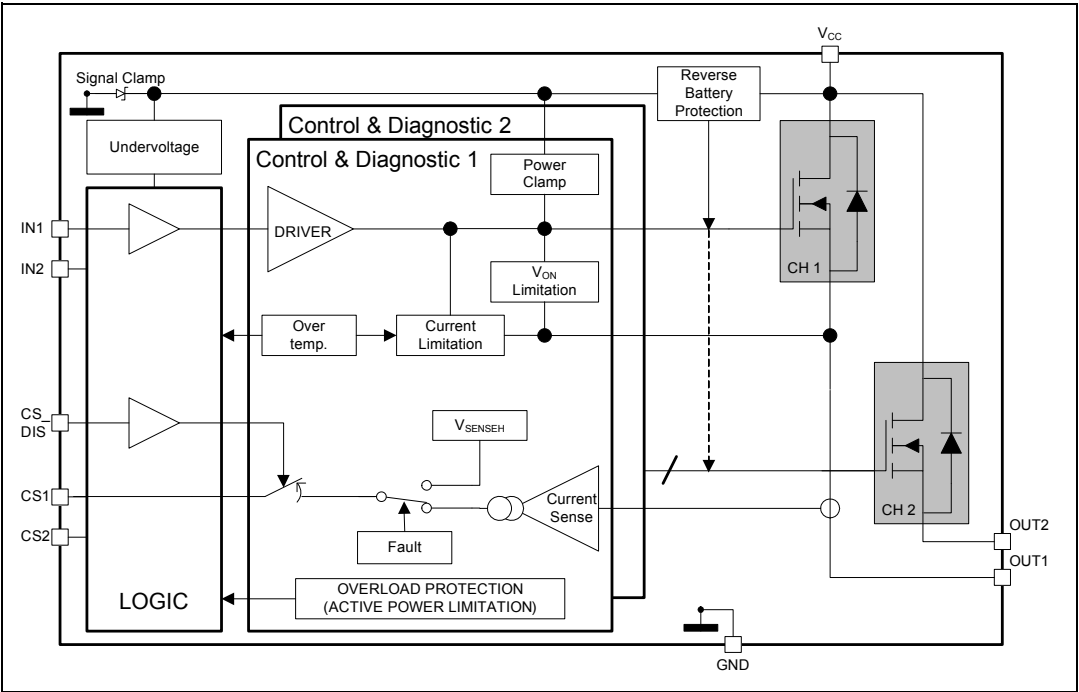


Table 1. Pin function

| Name               | Function                                                                                          |
|--------------------|---------------------------------------------------------------------------------------------------|
| V <sub>CC</sub>    | Battery connection                                                                                |
| OUT <sub>1,2</sub> | Power output                                                                                      |
| GND                | Ground connection                                                                                 |
| IN <sub>1,2</sub>  | Voltage controlled input pins with hysteresis, CMOS compatible. They controls output switch state |
| CS <sub>1,2</sub>  | Analog current sense pins, they deliver a current proportional to the load current                |
| CS_DIS             | Active high CMOS compatible pin, to disable the current sense pin                                 |

Figure 2. Configuration diagram (top view)

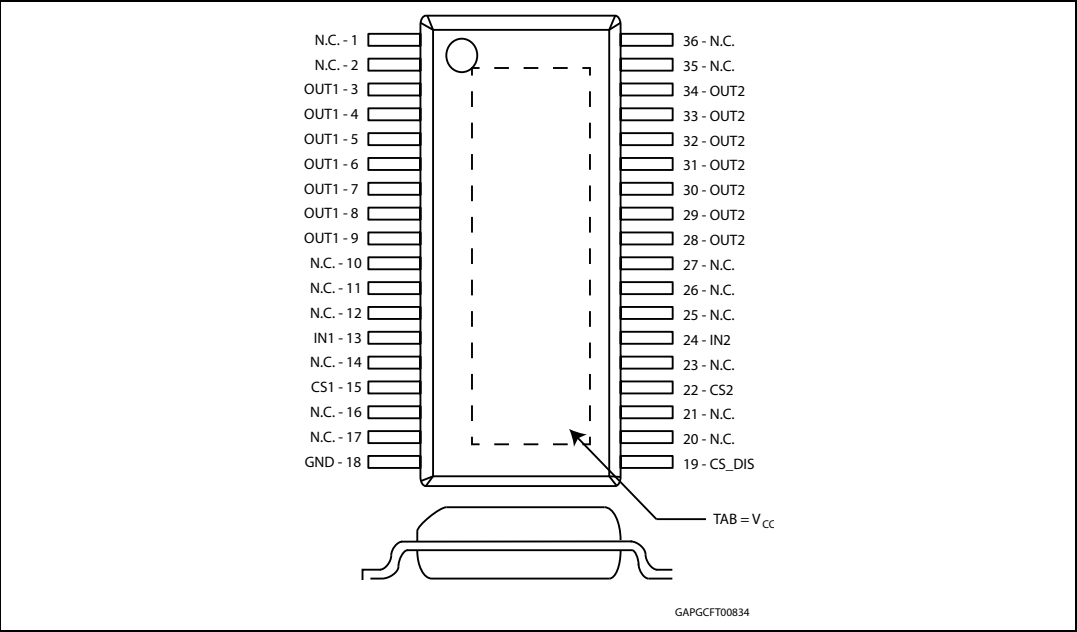


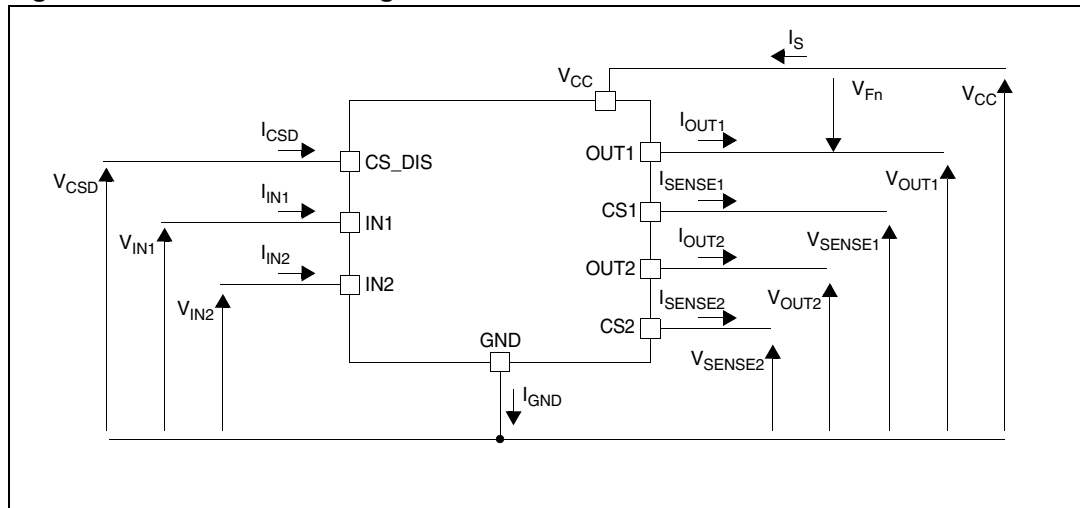
Table 2. Suggested connections for unused and not connected pins

| Connection / pin | Current sense         | N.C.             | Output      | Input                  | CS_DIS                 |
|------------------|-----------------------|------------------|-------------|------------------------|------------------------|
| Floating         | Not allowed           | X <sup>(1)</sup> | X           | X                      | X                      |
| To ground        | Through 1 KΩ resistor | X                | Not allowed | Through 10 KΩ resistor | Through 10 KΩ resistor |

1. X: do not care.

## 2 Electrical specifications

Figure 3. Current and voltage conventions



### 2.1 Absolute maximum ratings

Stressing the device above the rating listed in the [Table 3](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to the conditions in table below for extended periods may affect device reliability.

Table 3. Absolute maximum ratings

| Symbol        | Parameter                                                                                                                                                               | Value                      | Unit   |
|---------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------|--------|
| $V_{CC}$      | DC supply voltage                                                                                                                                                       | 41                         | V      |
| $-V_{CC}$     | Reverse DC supply voltage                                                                                                                                               | 16                         | V      |
| $V_{CC\_LSC}$ | Maximum supply voltage for full protection to short-circuit (AEC-Q100-012)                                                                                              | 18                         | V      |
| $I_{OUT}$     | DC output current                                                                                                                                                       | Internally limited         | A      |
| $-I_{OUT}$    | Reverse DC output current                                                                                                                                               | 35                         | A      |
| $I_{IN}$      | DC input current                                                                                                                                                        | -1 to 10                   | mA     |
| $I_{CSD}$     | DC current sense disable input current                                                                                                                                  | -1 to 10                   | mA     |
| $V_{CSENSE}$  | Current sense maximum voltage                                                                                                                                           | $V_{CC} - 41$<br>$+V_{CC}$ | V<br>V |
| $E_{MAX}$     | Maximum switching energy (single pulse)<br>( $L = 0.26$ mH; $R_L = 0$ $\Omega$ ; $V_{BAT} = 13.5$ V; $T_{jstart} = 150^\circ\text{C}$ ;<br>$I_{OUT} = I_{limL}(Typ.)$ ) | 29                         | mJ     |

**Table 3. Absolute maximum ratings (continued)**

| Symbol    | Parameter                                                                                      | Value      | Unit |
|-----------|------------------------------------------------------------------------------------------------|------------|------|
| $V_{ESD}$ | Electrostatic discharge<br>(human body model: $R = 1.5\text{ K}\Omega$ ; $C = 100\text{ pF}$ ) |            |      |
|           | – IN                                                                                           | 4000       | V    |
|           | – CS                                                                                           | 2000       |      |
|           | – CS_DIS                                                                                       | 4000       |      |
|           | – OUT                                                                                          | 5000       |      |
|           | – $V_{CC}$                                                                                     | 5000       |      |
| $V_{ESD}$ | Charge device model (CDM-AEC-Q100-011)                                                         | 750        | V    |
| $T_j$     | Junction operating temperature                                                                 | -40 to 150 | °C   |
| $T_{stg}$ | Storage temperature                                                                            | -55 to 150 | °C   |

## 2.2 Thermal data

**Table 4. Thermal data**

| Symbol         | Parameter                                              | Maximum value                                        | Unit |
|----------------|--------------------------------------------------------|------------------------------------------------------|------|
| $R_{thj-case}$ | Thermal resistance junction-case (with one channel on) | 1.4                                                  | °C/W |
| $R_{thj-amb}$  | Thermal resistance junction-ambient (MAX)              | See <a href="#">Figure 35</a> in the thermal section | °C/W |



## 2.3 Electrical characteristics

Values specified in this section are for  $8\text{ V} < V_{CC} < 28\text{ V}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ , unless otherwise specified.

**Table 5. Power section**

| Symbol              | Parameter                               | Test conditions                                                                                                      | Min. | Typ.             | Max.             | Unit          |
|---------------------|-----------------------------------------|----------------------------------------------------------------------------------------------------------------------|------|------------------|------------------|---------------|
| $V_{CC}$            | Operating supply voltage                |                                                                                                                      | 4.5  | 13               | 28               | V             |
| $V_{USD}$           | Undervoltage shutdown                   |                                                                                                                      |      | 3.5              | 4.5              | V             |
| $V_{USDhyst}$       | Undervoltage shutdown hysteresis        |                                                                                                                      |      | 0.5              |                  | V             |
| $R_{ON}$            | ON-state resistance                     | $I_{OUT} = 3\text{ A}$ ; $T_j = 25^\circ\text{C}$                                                                    |      | 25               |                  | m $\Omega$    |
|                     |                                         | $I_{OUT} = 3\text{ A}$ ; $T_j = 150^\circ\text{C}$                                                                   |      |                  | 50               |               |
|                     |                                         | $I_{OUT} = 3\text{ A}$ ; $V_{CC} = 5\text{ V}$ ; $T_j = 25^\circ\text{C}$                                            |      | 35               |                  |               |
| $R_{ON\text{ REV}}$ | Reverse battery ON-state resistance     | $V_{CC} = -13\text{ V}$ ; $I_{OUT} = -3\text{ A}$ ; $T_j = 25^\circ\text{C}$                                         |      | 25               |                  | m $\Omega$    |
| $V_{clamp}$         | Clamp voltage                           | $I_S = 20\text{ mA}$                                                                                                 | 41   | 46               | 52               | V             |
| $I_S$               | Supply current                          | Off-state: $V_{CC} = 13\text{ V}$ ; $T_j = 25^\circ\text{C}$ ; $V_{IN} = V_{OUT} = V_{SENSE} = V_{CSD} = 0\text{ V}$ |      | 2 <sup>(1)</sup> | 5 <sup>(1)</sup> | $\mu\text{A}$ |
|                     |                                         | On-state: $V_{CC} = 13\text{ V}$ ; $V_{IN} = 5\text{ V}$ ; $I_{OUT} = 0\text{ A}$                                    |      | 3.5              | 6.5              | mA            |
| $I_{L(off)}$        | OFF-state output current <sup>(2)</sup> | $V_{IN} = V_{OUT} = 0\text{ V}$ ; $V_{CC} = 13\text{ V}$ ; $T_j = 25^\circ\text{C}$                                  | 0    | 0.01             | 3                | $\mu\text{A}$ |
|                     |                                         | $V_{IN} = V_{OUT} = 0\text{ V}$ ; $V_{CC} = 13\text{ V}$ ; $T_j = 125^\circ\text{C}$                                 | 0    |                  | 5                |               |

1. PowerMOS leakage included.

2. For each channel.

**Table 6. Switching ( $V_{CC} = 13\text{ V}$ ;  $T_j = 25^\circ\text{C}$ )**

| Symbol                | Parameter                                 | Test conditions                                           | Min. | Typ.                          | Max. | Unit             |
|-----------------------|-------------------------------------------|-----------------------------------------------------------|------|-------------------------------|------|------------------|
| $t_{d(on)}$           | Turn-on delay time                        | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 6</a> ) | —    | 20                            | —    | $\mu\text{s}$    |
| $t_{d(off)}$          | Turn-off delay time                       | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 6</a> ) | —    | 20                            | —    | $\mu\text{s}$    |
| $(dV_{OUT}/dt)_{on}$  | Turn-on voltage slope                     | $R_L = 4.3\text{ }\Omega$                                 | —    | See <a href="#">Figure 26</a> | —    | V/ $\mu\text{s}$ |
| $(dV_{OUT}/dt)_{off}$ | Turn-off voltage slope                    | $R_L = 4.3\text{ }\Omega$                                 | —    | See <a href="#">Figure 27</a> | —    | V/ $\mu\text{s}$ |
| $W_{ON}$              | Switching energy losses during $t_{won}$  | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 6</a> ) | —    | 0.25                          | —    | mJ               |
| $W_{OFF}$             | Switching energy losses during $t_{woff}$ | $R_L = 4.3\text{ }\Omega$ (see <a href="#">Figure 6</a> ) | —    | 0.3                           | —    | mJ               |

Table 7. Current sense ( $8\text{ V} < V_{CC} < 18\text{ V}$ )

| Symbol           | Parameter                                                     | Test conditions                                                                                                                                             | Min.         | Typ.         | Max.         | Unit          |
|------------------|---------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|--------------|--------------|---------------|
| $K_0$            | $I_{OUT}/I_{SENSE}$                                           | $I_{OUT} = 0.5\text{ A}$ ; $V_{SENSE} = 0.5\text{ V}$<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                   | 1000         | 2900         | 5000         |               |
| $K_1$            | $I_{OUT}/I_{SENSE}$                                           | $I_{OUT} = 2\text{ A}$ ; $V_{SENSE} = 0.5\text{ V}$<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$<br>$T_j = 25^\circ\text{C}$ to $150^\circ\text{C}$  | 1900<br>2240 | 3000<br>3000 | 3810<br>3520 |               |
| $dK_1/K_1^{(1)}$ | Current sense ratio drift                                     | $I_{OUT} = 2\text{ A}$ ; $V_{SENSE} = 0.5\text{ V}$ ;<br>$V_{CSD} = 0\text{ V}$ ;<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$                       | -9           |              | 9            | %             |
| $K_2$            | $I_{OUT}/I_{SENSE}$                                           | $I_{OUT} = 3\text{ A}$ ; $V_{SENSE} = 4\text{ V}$<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$<br>$T_j = 25^\circ\text{C}$ to $150^\circ\text{C}$    | 2230<br>2460 | 3000<br>3000 | 3550<br>3350 |               |
| $dK_2/K_2^{(1)}$ | Current sense ratio drift                                     | $I_{OUT} = 3\text{ A}$ ; $V_{SENSE} = 4\text{ V}$ ;<br>$V_{CSD} = 0\text{ V}$ ;<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$                         | -6           |              | 6            | %             |
| $K_3$            | $I_{OUT}/I_{SENSE}$                                           | $I_{OUT} = 10\text{ A}$ ; $V_{SENSE} = 4\text{ V}$<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$<br>$T_j = 25^\circ\text{C}$ to $150^\circ\text{C}$   | 2710<br>2780 | 2900<br>2900 | 3150<br>3080 |               |
| $dK_3/K_3^{(1)}$ | Current sense ratio drift                                     | $I_{OUT} = 10\text{ A}$ ; $V_{SENSE} = 4\text{ V}$ ;<br>$V_{CSD} = 0\text{ V}$ ;<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$                        | -3           |              | 3            | %             |
| $I_{SENSE0}$     | Analog sense leakage current                                  | $I_{OUT} = 0\text{ A}$ ; $V_{SENSE} = 0\text{ V}$ ;<br>$V_{CSD} = 5\text{ V}$ ; $V_{IN} = 0\text{ V}$ ;<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$ | 0            |              | 1            | $\mu\text{A}$ |
|                  |                                                               | $I_{OUT} = 0\text{ A}$ ; $V_{SENSE} = 0\text{ V}$ ;<br>$V_{CSD} = 0\text{ V}$ ; $V_{IN} = 5\text{ V}$ ;<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$ | 0            |              | 2            |               |
|                  |                                                               | $I_{OUT} = 3\text{ A}$ ; $V_{SENSE} = 0\text{ V}$ ;<br>$V_{CSD} = V_{IN} = 5\text{ V}$ ;                                                                    | 0            |              | 1            |               |
| $V_{SENSE}$      | Max analog sense output voltage                               | $I_{OUT} = 15\text{ A}$ ; $V_{CSD} = 0\text{ V}$                                                                                                            | 5            |              |              | V             |
| $V_{SENSEH}$     | Analog sense output voltage in fault condition <sup>(2)</sup> | $V_{CC} = 13\text{ V}$ ; $R_{SENSE} = 10\text{ K}\Omega$                                                                                                    |              | 8            |              | V             |
| $I_{SENSEH}$     | Analog sense output current in fault condition <sup>(2)</sup> | $V_{CC} = 13\text{ V}$ ; $V_{SENSE} = 5\text{ V}$                                                                                                           |              | 9            |              | mA            |
| $t_{DSENSE1H}$   | Delay response time from falling edge of CS_DIS pin           | $V_{SENSE} < 4\text{ V}$ ;<br>$0.5\text{ A} < I_{OUT} < 10\text{ A}$ ;<br>$I_{SENSE} = 90\%$ of $I_{SENSE\text{ max}}$<br>(see <a href="#">Figure 4</a> )   |              | 20           | 100          | $\mu\text{s}$ |
| $t_{DSENSE1L}$   | Delay response time from rising edge of CS_DIS pin            | $V_{SENSE} < 4\text{ V}$ ;<br>$0.5\text{ A} < I_{OUT} < 10\text{ A}$ ;<br>$I_{SENSE} = 10\%$ of $I_{SENSE\text{ max}}$<br>(see <a href="#">Figure 4</a> )   |              | 5            | 20           | $\mu\text{s}$ |

**Table 7. Current sense (8 V < V<sub>CC</sub> < 18 V) (continued)**

| Symbol                 | Parameter                                                                                  | Test conditions                                                                                                                                                                                 | Min. | Typ. | Max. | Unit |
|------------------------|--------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| t <sub>DSENSE2H</sub>  | Delay response time from rising edge of IN pin                                             | V <sub>SENSE</sub> < 4 V;<br>0.5 A < I <sub>OUT</sub> < 10 A;<br>I <sub>SENSE</sub> = 90 % of I <sub>SENSE max</sub><br>(see <a href="#">Figure 4</a> )                                         |      | 70   | 300  | μs   |
| Δt <sub>DSENSE2H</sub> | Delay response time between rising edge of output current and rising edge of current sense | V <sub>SENSE</sub> < 4V;<br>I <sub>SENSE</sub> = 90 % of I <sub>SENSEMAX</sub> ,<br>I <sub>OUT</sub> = 90 % of I <sub>OUTMAX</sub><br>I <sub>OUTMAX</sub> = 3 A (see <a href="#">Figure 7</a> ) |      |      | 100  | μs   |
| t <sub>DSENSE2L</sub>  | Delay response time from falling edge of IN pin                                            | V <sub>SENSE</sub> < 4 V;<br>0.5 A < I <sub>OUT</sub> < 10 A;<br>I <sub>SENSE</sub> = 10 % of I <sub>SENSE max</sub><br>(see <a href="#">Figure 4</a> )                                         |      | 5    | 50   | μs   |

1. Parameter guaranteed by design; it is not tested.

2. Fault condition includes: power limitation, overtemperature and open-load OFF-state detection.

**Table 8. Open-load detection (8 V < V<sub>CC</sub> < 18 V)**

| Symbol              | Parameter                                                                             | Test conditions                                                                                    | Min. | Typ. | Max. | Unit |
|---------------------|---------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------|------|------|------|------|
| V <sub>OL</sub>     | Open-load off-state voltage detection threshold                                       | V <sub>IN</sub> = 0 V; 8 V < V <sub>CC</sub> < 18 V                                                | 2    | —    | 4    | V    |
| I <sub>OL</sub>     | Open-load on-state current detection threshold                                        | V <sub>IN</sub> = 5 V;<br>8 V < V <sub>CC</sub> < 18 V;<br>I <sub>SENSE</sub> = 5 μA               |      | —    | 45   | mA   |
| t <sub>DSTKON</sub> | Output short circuit to V <sub>CC</sub> detection delay at turn off                   | See <a href="#">Figure 5</a>                                                                       | 180  | —    | 1200 | μs   |
| td_vol              | Delay response from output rising edge to V <sub>SENSE</sub> rising edge in open-load | V <sub>IN</sub> = 0 V; V <sub>OUT</sub> = 4 V;<br>V <sub>SENSE</sub> = 90 % of V <sub>SENSEH</sub> |      | —    | 20   | μs   |
| I <sub>LOFF2</sub>  | Off-state output current                                                              | V <sub>OUT</sub> = 4 V                                                                             | -75  | —    | 0    | μA   |

**Table 9. Protections and diagnostics<sup>(1)</sup>**

| Symbol            | Parameter                                    | Test conditions                                                            | Min.                | Typ.                | Max. | Unit |
|-------------------|----------------------------------------------|----------------------------------------------------------------------------|---------------------|---------------------|------|------|
| I <sub>limH</sub> | DC short-circuit current                     | V <sub>CC</sub> = 13 V                                                     | 33                  | 47                  | 66   | A    |
|                   |                                              | 5 V < V <sub>CC</sub> < 18 V                                               |                     |                     | 66   |      |
| I <sub>limL</sub> | Short-circuit current during thermal cycling | V <sub>CC</sub> = 13 V; T <sub>R</sub> < T <sub>j</sub> < T <sub>TSD</sub> |                     | 12                  |      | A    |
| T <sub>TSD</sub>  | Shutdown temperature                         |                                                                            | 150                 | 175                 | 200  | °C   |
| T <sub>R</sub>    | Reset temperature                            |                                                                            | T <sub>RS</sub> + 1 | T <sub>RS</sub> + 5 |      | °C   |
| T <sub>RS</sub>   | Thermal reset of status                      |                                                                            | 135                 |                     |      | °C   |

**Table 9. Protections and diagnostics<sup>(1)</sup> (continued)**

| Symbol      | Parameter                              | Test conditions                                                                                                   | Min.          | Typ.          | Max.          | Unit |
|-------------|----------------------------------------|-------------------------------------------------------------------------------------------------------------------|---------------|---------------|---------------|------|
| $T_{HYST}$  | Thermal hysteresis ( $T_{TSD} - T_R$ ) |                                                                                                                   |               | 7             |               | °C   |
| $V_{DEMAG}$ | Turn-off output voltage clamp          | $I_{OUT} = 2\text{ A}$ ; $V_{IN} = 0\text{ V}$ ;<br>$L = 6\text{ mH}$ ; $T_j = -40^\circ\text{C}$                 | $V_{CC} - 39$ | $V_{CC} - 46$ | $V_{CC} - 52$ | V    |
|             |                                        | $I_{OUT} = 2\text{ A}$ ; $V_{IN} = 0$ ;<br>$L = 6\text{ mH}$ ; $25^\circ\text{C} < T_j < 150^\circ\text{C}$       | $V_{CC} - 41$ | $V_{CC} - 46$ | $V_{CC} - 52$ | V    |
| $V_{ON}$    | Output voltage drop limitation         | $I_{OUT} = 0.1\text{ A}$ ;<br>$T_j = -40^\circ\text{C}$ to $150^\circ\text{C}$<br>(see <a href="#">Figure 8</a> ) |               | 25            |               | mV   |

1. To ensure long term reliability under heavy overload or short-circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device is subjected to abnormal conditions, this software must limit the duration and number of activation cycles.

**Table 10. Logic inputs**

| Symbol          | Parameter                 | Test conditions          | Min. | Typ. | Max. | Unit |
|-----------------|---------------------------|--------------------------|------|------|------|------|
| $V_{IL}$        | Low-level input voltage   |                          |      |      | 0.9  | V    |
| $I_{IL}$        | Low-level input current   | $V_{IN} = 0.9\text{ V}$  | 1    |      |      | μA   |
| $V_{IH}$        | High-level input voltage  |                          | 2.1  |      |      | V    |
| $I_{IH}$        | High-level input current  | $V_{IN} = 2.1\text{ V}$  |      |      | 10   | μA   |
| $V_{I(hyst)}$   | Input hysteresis voltage  |                          | 0.25 |      |      | V    |
| $V_{ICL}$       | Input clamp voltage       | $I_{IN} = 1\text{ mA}$   | 5.5  |      | 7    | V    |
|                 |                           | $I_{IN} = -1\text{ mA}$  |      | -0.7 |      |      |
| $V_{CSDL}$      | Low-level CS_DIS voltage  |                          |      |      | 0.9  | V    |
| $I_{CSDL}$      | Low-level CS_DIS current  | $V_{CSD} = 0.9\text{ V}$ | 1    |      |      | μA   |
| $V_{CSDH}$      | High-level CS_DIS voltage |                          | 2.1  |      |      | V    |
| $I_{CSDH}$      | High-level CS_DIS current | $V_{CSD} = 2.1\text{ V}$ |      |      | 10   | μA   |
| $V_{CSD(hyst)}$ | CS_DIS hysteresis voltage |                          | 0.25 |      |      | V    |
| $V_{CSCL}$      | CS_DIS clamp voltage      | $I_{CSD} = 1\text{ mA}$  | 5.5  |      | 7    | V    |
|                 |                           | $I_{CSD} = -1\text{ mA}$ |      | -0.7 |      |      |

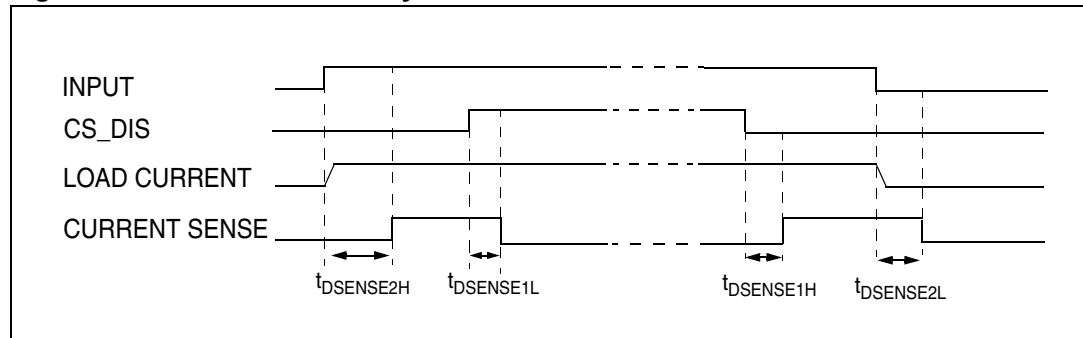
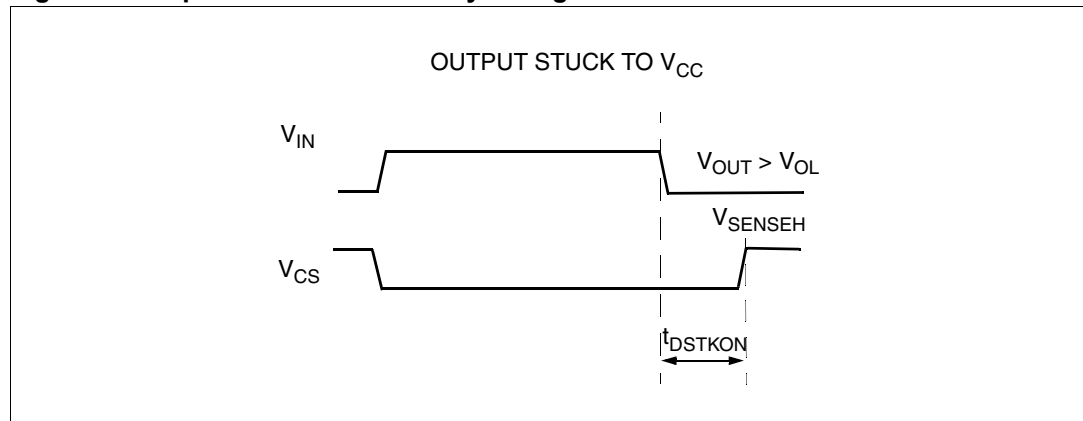
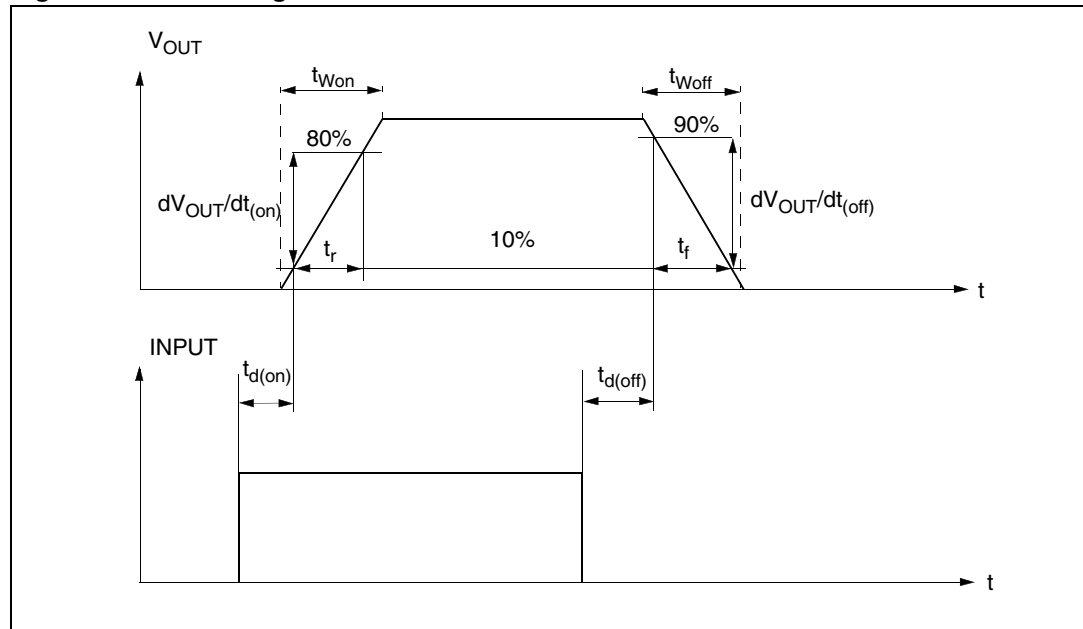
**Figure 4. Current sense delay characteristics****Figure 5. Open-load off-state delay timing****Figure 6. Switching characteristics**

Figure 7. Delay response time between rising edge of output current and rising edge of current sense (CS enabled)

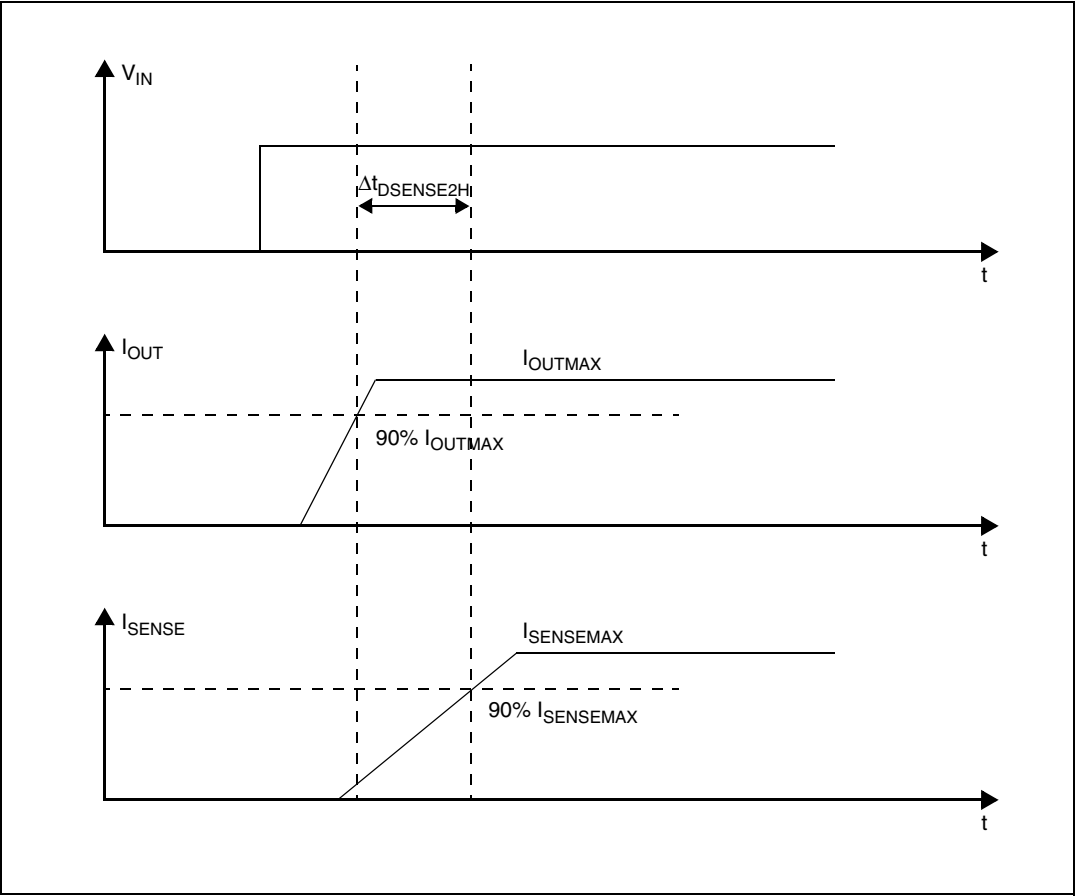
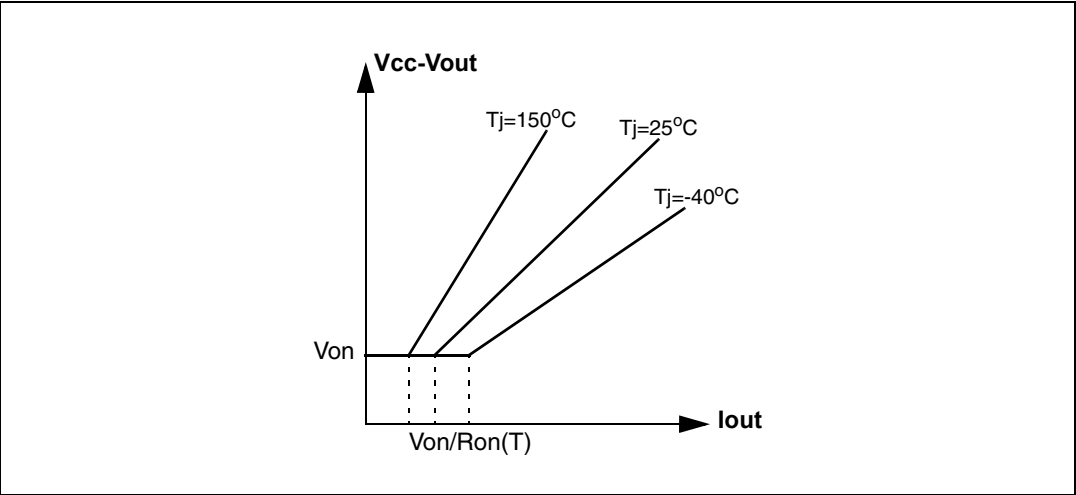
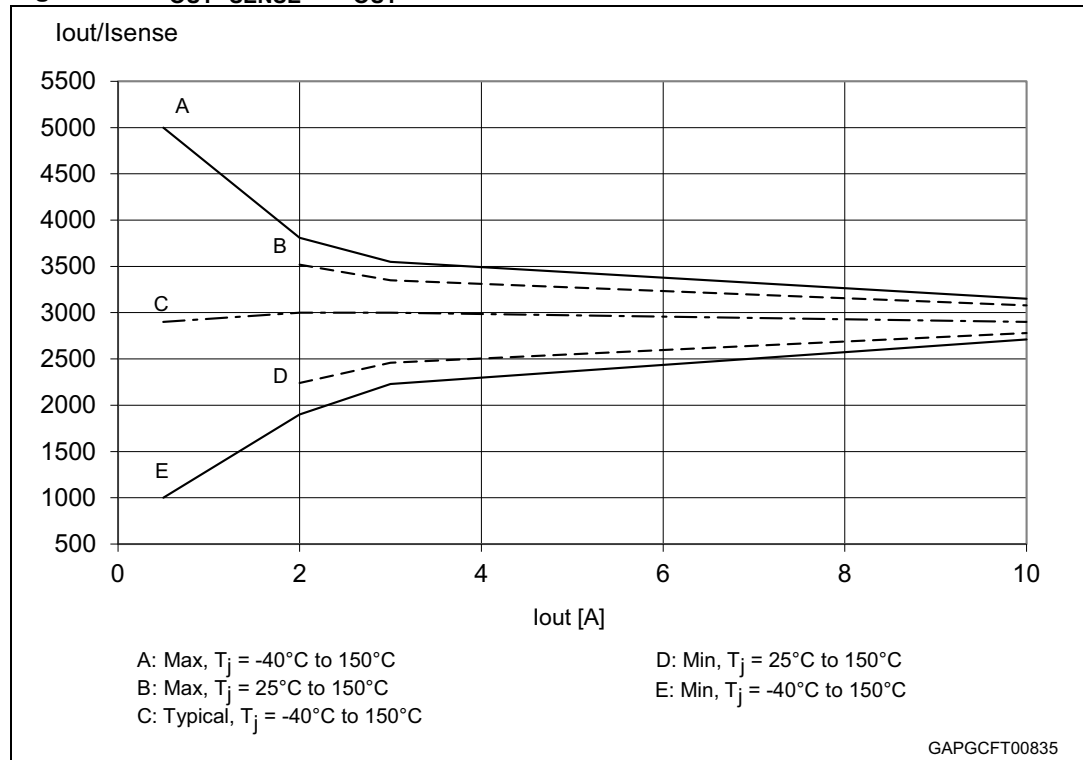
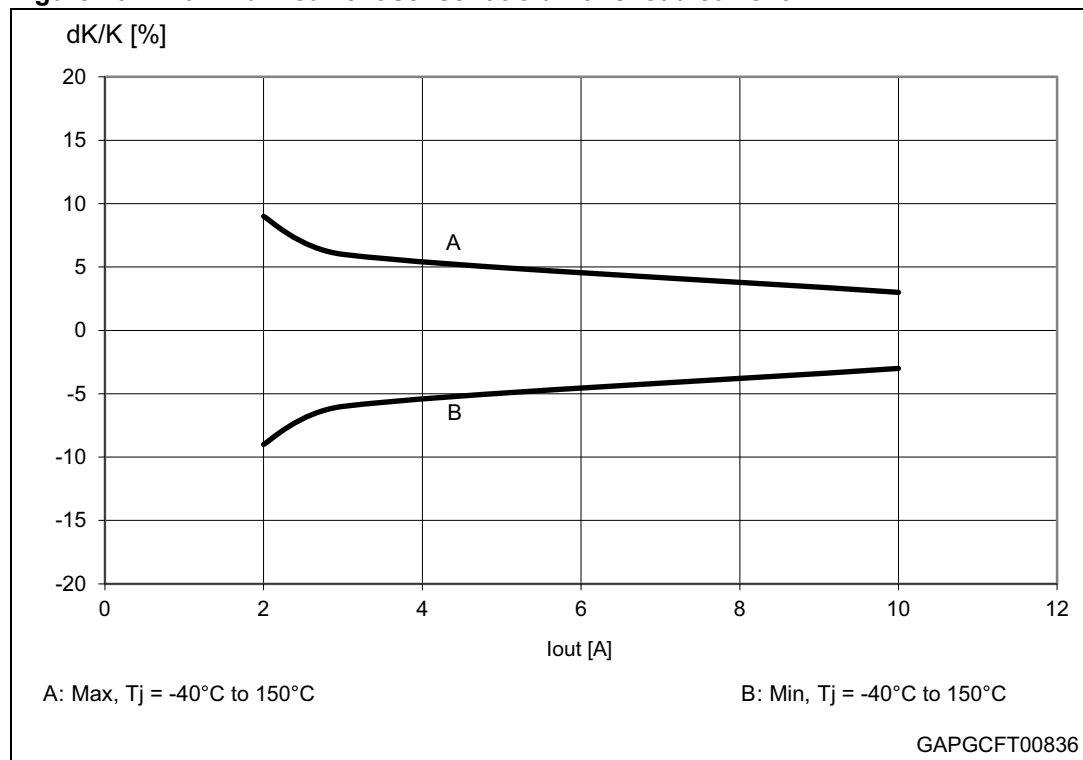


Figure 8. Output voltage drop limitation



**Figure 9.**  $I_{OUT}/I_{SENSE}$  vs  $I_{OUT}$ **Figure 10.** Maximum current sense ratio drift vs load current

1. Parameter guaranteed by design; it is not tested.

Table 11. Truth table

| Conditions                                                      | Input | Output                        | Sense ( $V_{CSD} = 0\text{ V}$ ) <sup>(1)</sup> |
|-----------------------------------------------------------------|-------|-------------------------------|-------------------------------------------------|
| Normal operation                                                | L     | L                             | 0                                               |
|                                                                 | H     | H                             | Nominal                                         |
| Overtemperature                                                 | L     | L                             | 0                                               |
|                                                                 | H     | L                             | $V_{SENSEH}$                                    |
| Undervoltage                                                    | L     | L                             | 0                                               |
|                                                                 | H     | L                             | 0                                               |
| Overload                                                        | H     | X<br>(no power limitation)    | Nominal                                         |
|                                                                 | H     | Cycling<br>(power limitation) | $V_{SENSEH}$                                    |
| Short-circuit to GND<br>(Power limitation)                      | L     | L                             | 0                                               |
|                                                                 | H     | L                             | $V_{SENSEH}$                                    |
| short-circuit to $V_{CC}$<br>(external pull up<br>disconnected) | L     | H                             | $V_{SENSEH}$                                    |
|                                                                 | H     | H                             | < Nominal                                       |
| Negative output voltage<br>clamp                                | L     | L                             | 0                                               |

1. If the  $V_{CSD}$  is high, the SENSE output is at a high impedance, its potential depends on leakage currents and external circuit.



**Table 12. Electrical transient requirements (part 1)**

| ISO 7637-2:<br>2004(E)<br>Test pulse | Test levels <sup>(1)</sup> |        | Number of<br>pulses or<br>test times | Burst cycle/pulse<br>repetition time |        | Delays and<br>impedance  |
|--------------------------------------|----------------------------|--------|--------------------------------------|--------------------------------------|--------|--------------------------|
|                                      | III                        | IV     |                                      |                                      |        |                          |
| 1                                    | -75 V                      | -100 V | 5000<br>pulses                       | 0.5 s                                | 5 s    | 2 ms, 10 $\Omega$        |
| 2a                                   | +37 V                      | +50 V  | 5000<br>pulses                       | 0.2 s                                | 5 s    | 50 $\mu$ s, 2 $\Omega$   |
| 3a                                   | -100 V                     | -150 V | 1 h                                  | 90 ms                                | 100 ms | 0.1 $\mu$ s, 50 $\Omega$ |
| 3b                                   | +75 V                      | +100 V | 1 h                                  | 90 ms                                | 100 ms | 0.1 $\mu$ s, 50 $\Omega$ |
| 4                                    | -6 V                       | -7 V   | 1 pulse                              |                                      |        | 100 ms, 0.01 $\Omega$    |
| 5b <sup>(2)</sup>                    | +65 V                      | +87 V  | 1 pulse                              |                                      |        | 400 ms, 2 $\Omega$       |

1. The above test levels must be considered referred to  $V_{CC} = 13.5$  V except for pulse 5b

2. Valid in case of external load dump clamp: 40V maximum referred to ground.

**Table 13. Electrical transient requirements (part 2)**

| ISO 7637-2:<br>2004(E)<br>Test pulse | Test level results <sup>(1)</sup> |    |
|--------------------------------------|-----------------------------------|----|
|                                      | III                               | IV |
| 1                                    | C                                 | C  |
| 2a                                   | C                                 | C  |
| 3a                                   | C                                 | C  |
| 3b                                   | C                                 | C  |
| 4                                    | C                                 | C  |
| 5b <sup>(2)(3)</sup>                 | C                                 | C  |

1. The above test levels must be considered referred to  $V_{CC} = 13.5$  V except for pulse 5b

2. Valid in case of external load dump clamp: 40 V maximum referred to ground.

3. Suppressed load dump (pulse 5b) is withstood with a minimum load connected as specified in [Table 3: Absolute maximum ratings](#).

**Table 14. Electrical transient requirements (part 3)**

| Class | Contents                                                                                                                                                                 |
|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C     | All functions of the device are performed as designed after exposure to disturbance.                                                                                     |
| E     | One or more functions of the device are not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device. |

2.4 Waveforms

Figure 11. Normal operation

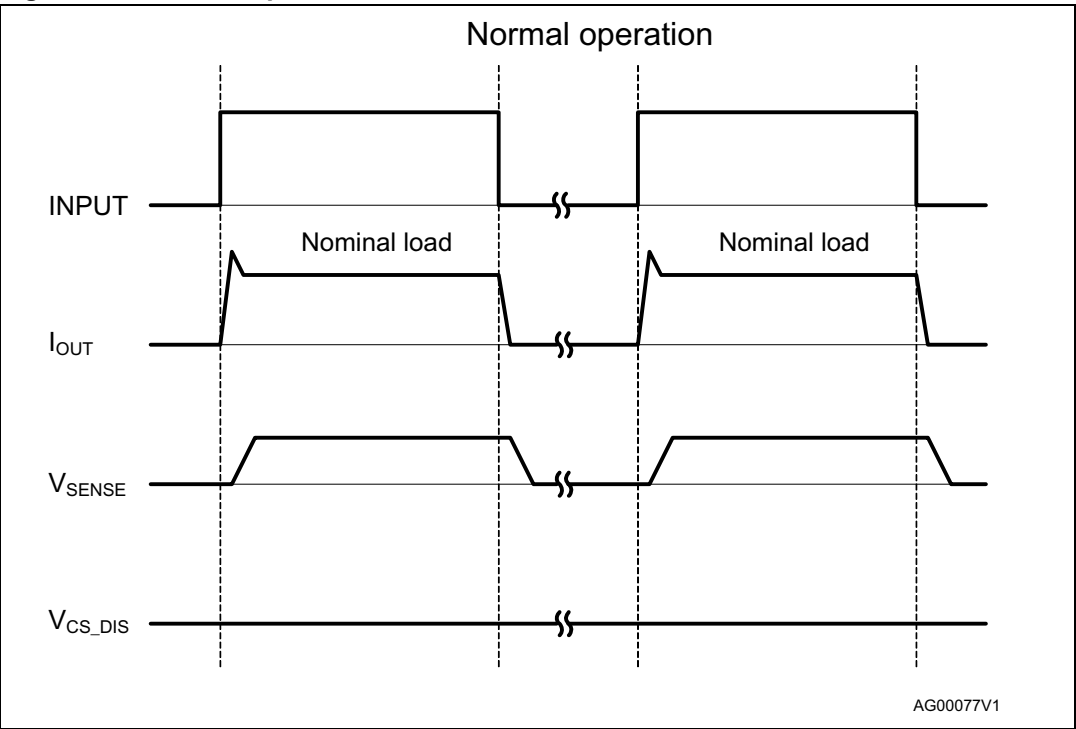


Figure 12. Overload or short to GND

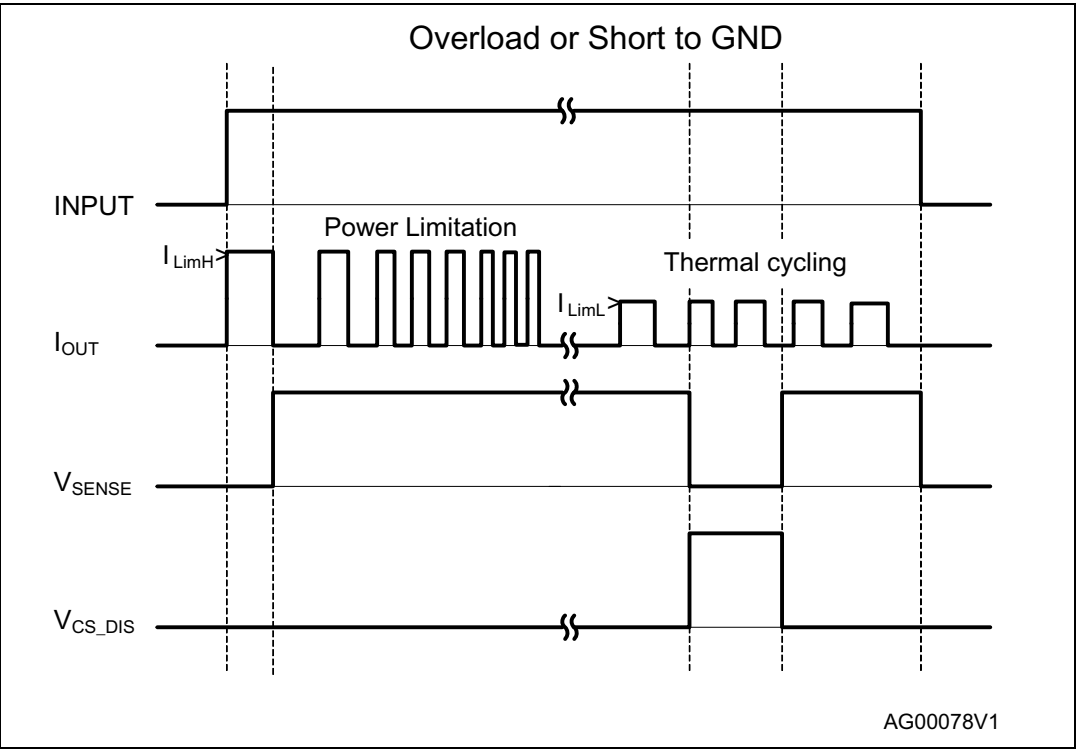


Figure 13. Intermittent overload

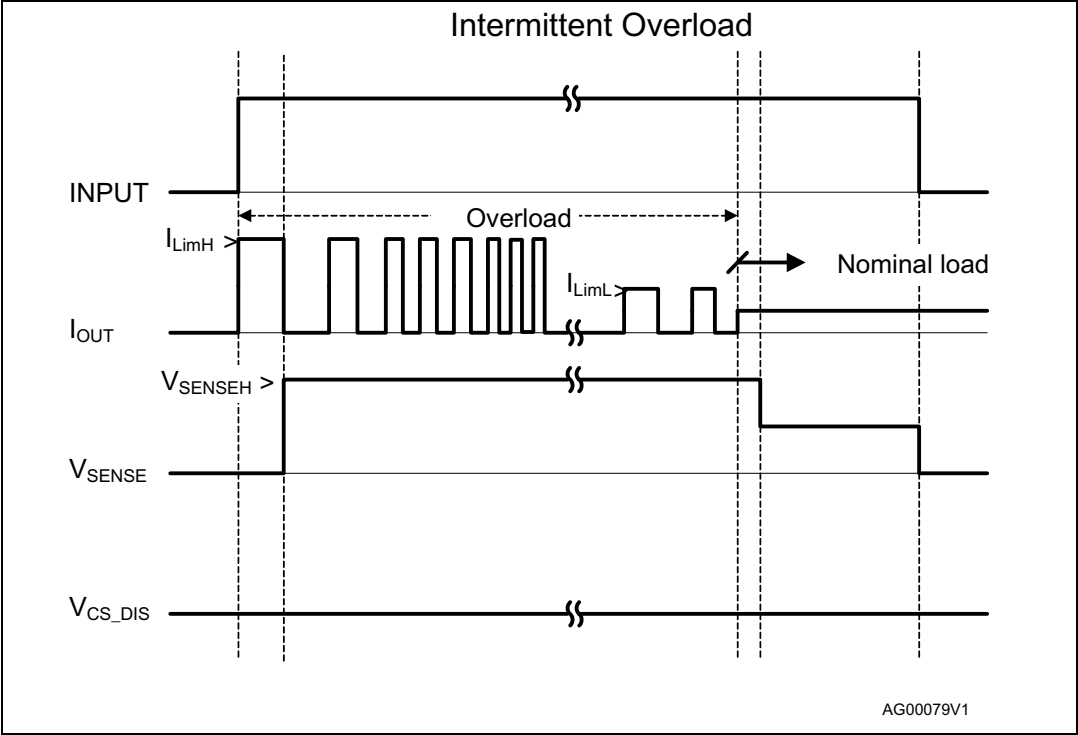


Figure 14. Short to V<sub>CC</sub>

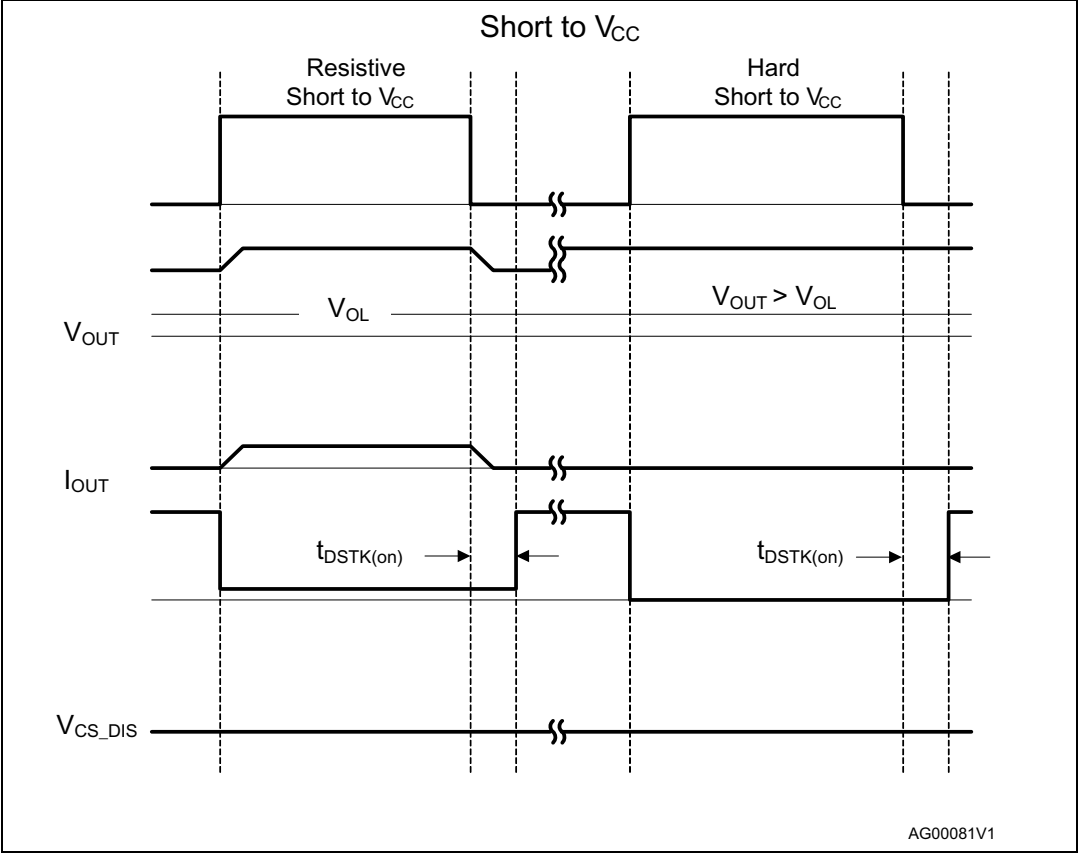
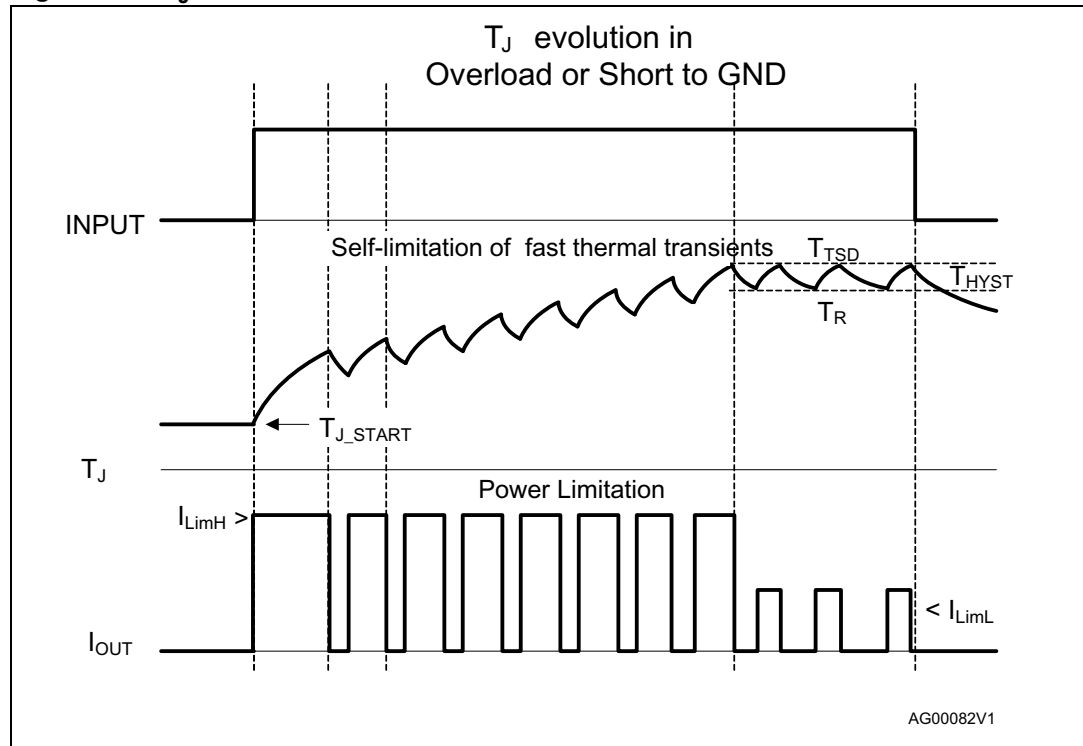


Figure 15.  $T_J$  evolution in overload or short to GND

2.5 Electrical characteristics curves

Figure 16. Off-state output current

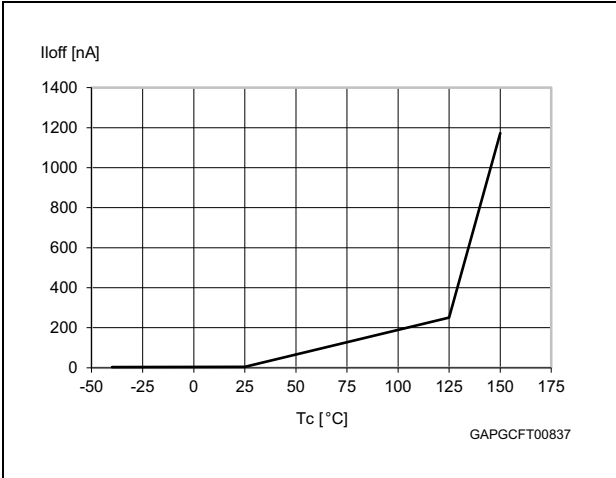


Figure 17. High-level input current

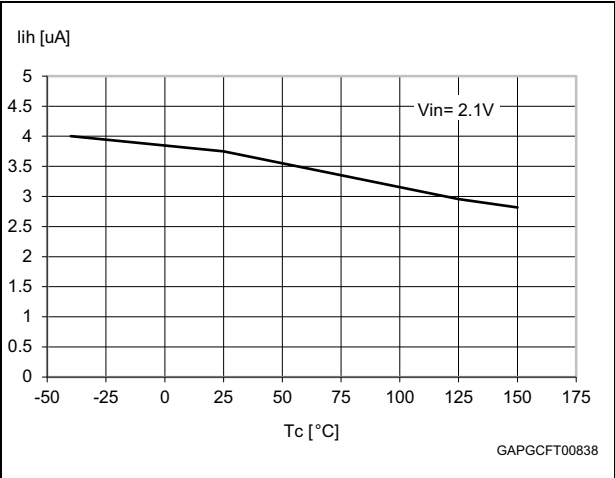


Figure 18. Input clamp voltage

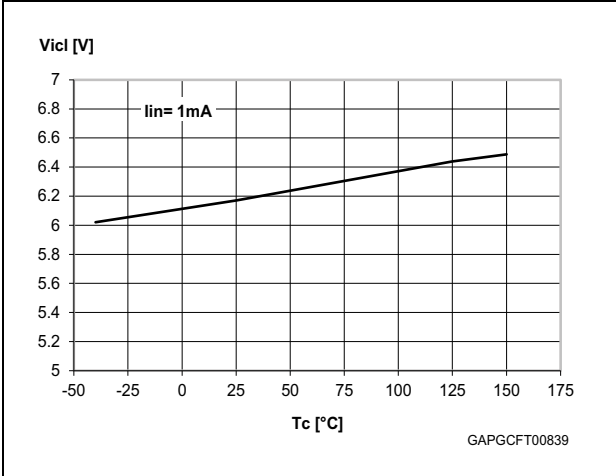


Figure 19. High-level input voltage

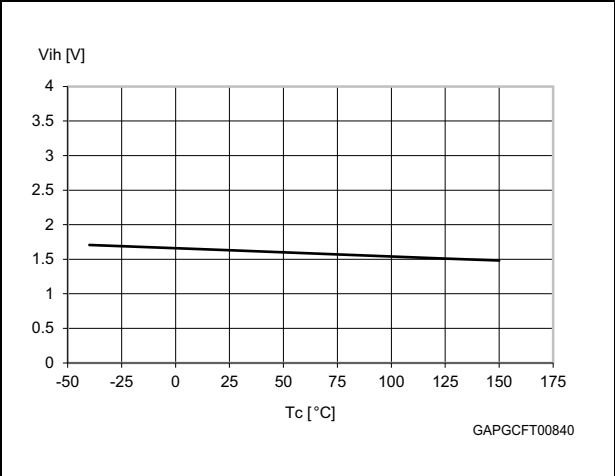


Figure 20. Low-level input voltage

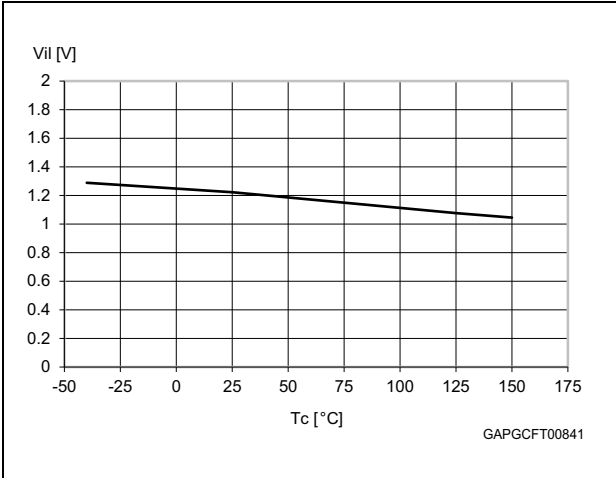


Figure 21. Input hysteresis voltage

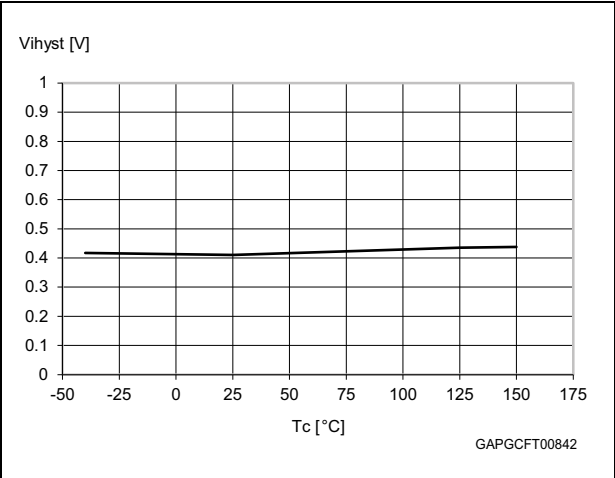


Figure 22. On-state resistance vs  $T_{case}$

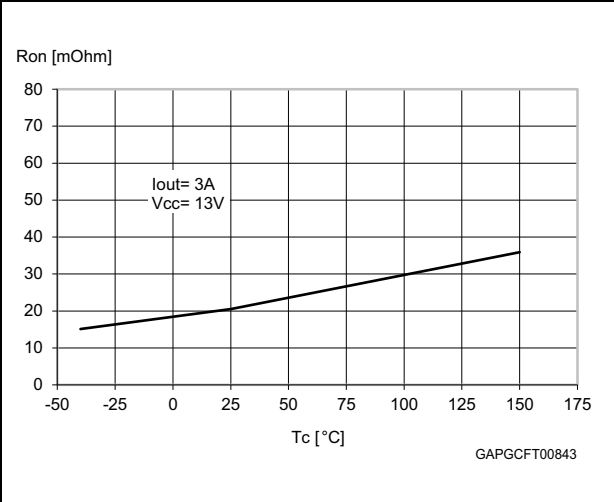


Figure 23. On-state resistance vs  $V_{CC}$

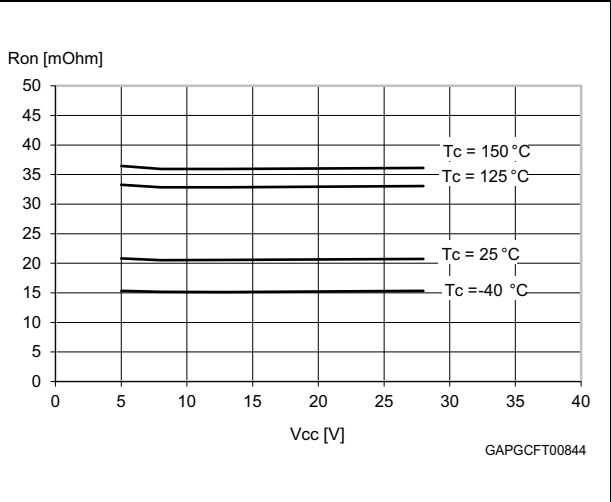


Figure 24. Undervoltage shutdown

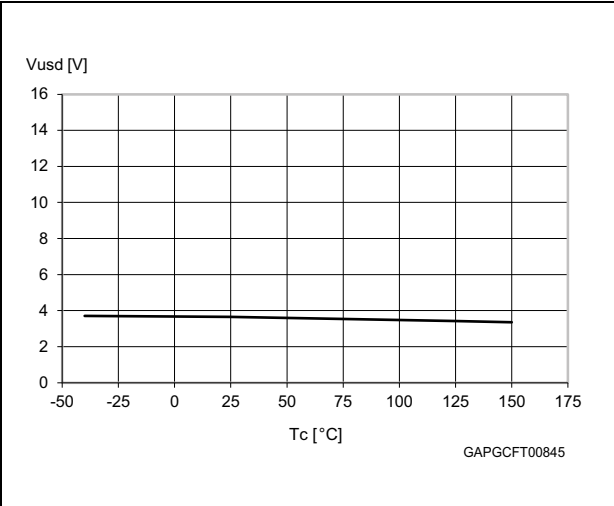


Figure 25.  $I_{LIMH}$  vs  $T_{case}$

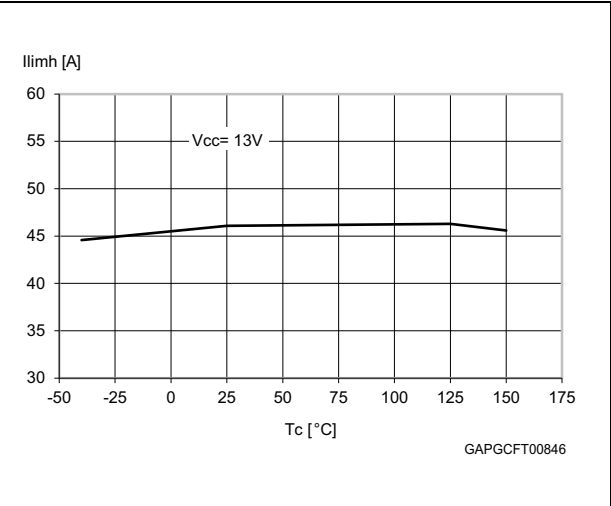


Figure 26. Turn-on voltage slope

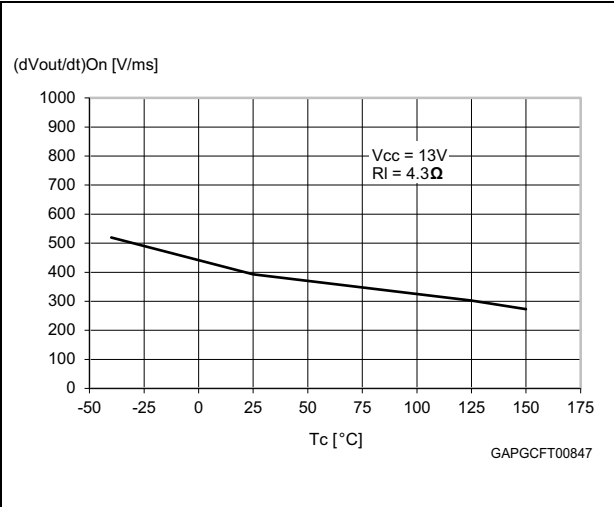


Figure 27. Turn-off voltage slope

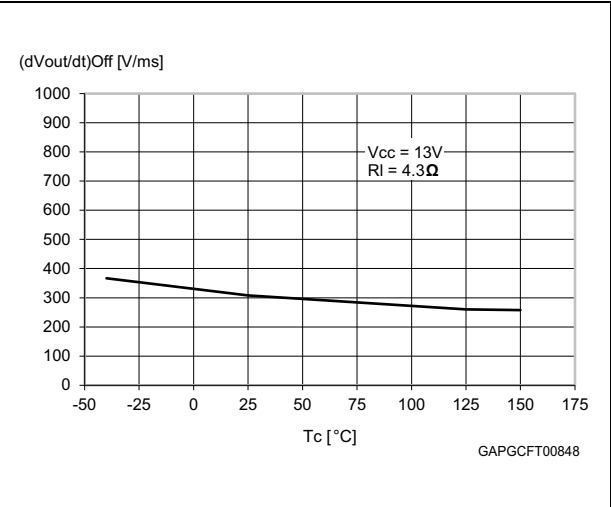


Figure 28. CS\_DIS clamp voltage

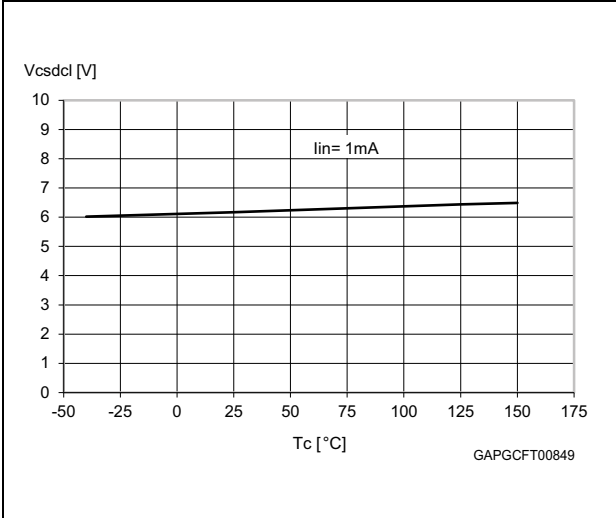


Figure 29. Low-level CS\_DIS voltage

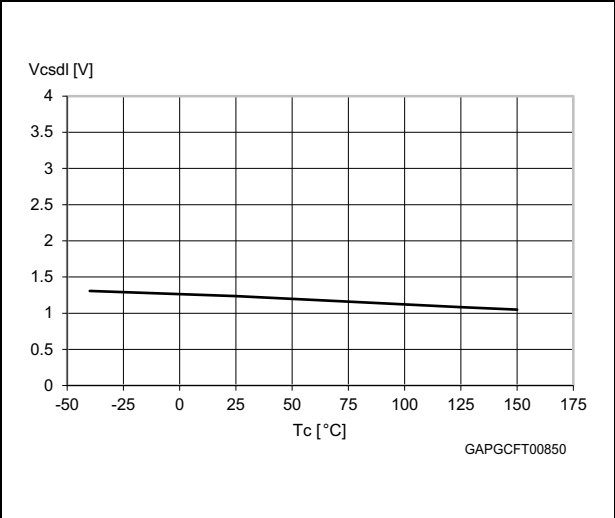
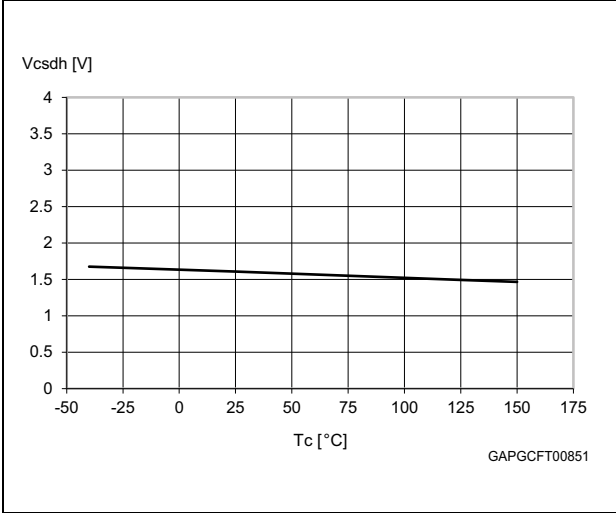
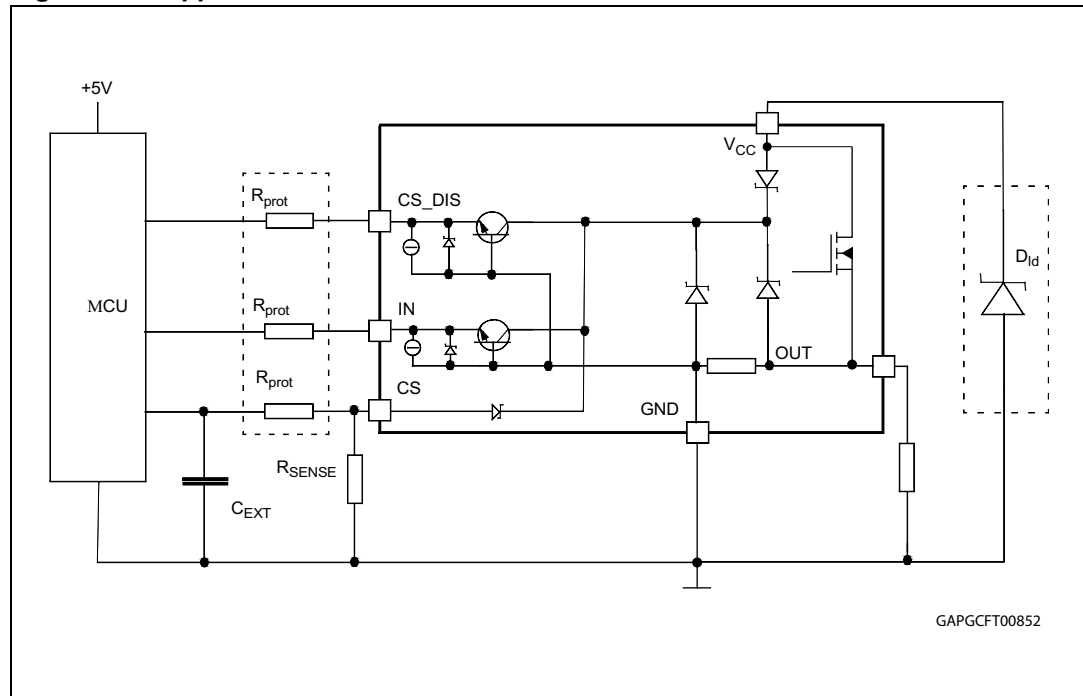


Figure 30. High-level CS\_DIS voltage



### 3 Application information

Figure 31. Application schematic



1. Channel 2 has the same internal circuit as channel 1.

#### 3.1 Load dump protection

$D_{Id}$  is necessary (voltage transient suppressor) if the load dump peak voltage exceeds the  $V_{CCPK}$  max rating. The same applies if the device is subject to transients on the  $V_{CC}$  line that are greater than the ones shown in the ISO 7637-2: 2004(E) table.

#### 3.2 MCU I/Os protection

When negative transients are present on the  $V_{CC}$  line, the control pins are pulled negative to approximately -1.5 V.

ST suggests the insertion of resistors ( $R_{prot}$ ) in the lines to prevent the microcontroller I/O pins from latching up.

The values of these resistors provide a compromise between the leakage current of the microcontroller, the current required by the HSD I/Os (input levels compatibility) and the latch-up limit of the microcontroller I/Os.



**Equation 1**

$$-V_{CCpeak} / I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH}) / I_{IHmax}$$

Calculation example:

For  $V_{CCpeak} = -1.5 \text{ V}$ ;  $I_{latchup} \geq 20 \text{ mA}$ ;  $V_{OH\mu C} \geq 4.5 \text{ V}$

$$75 \Omega \leq R_{prot} \leq 240 \text{ k}\Omega$$

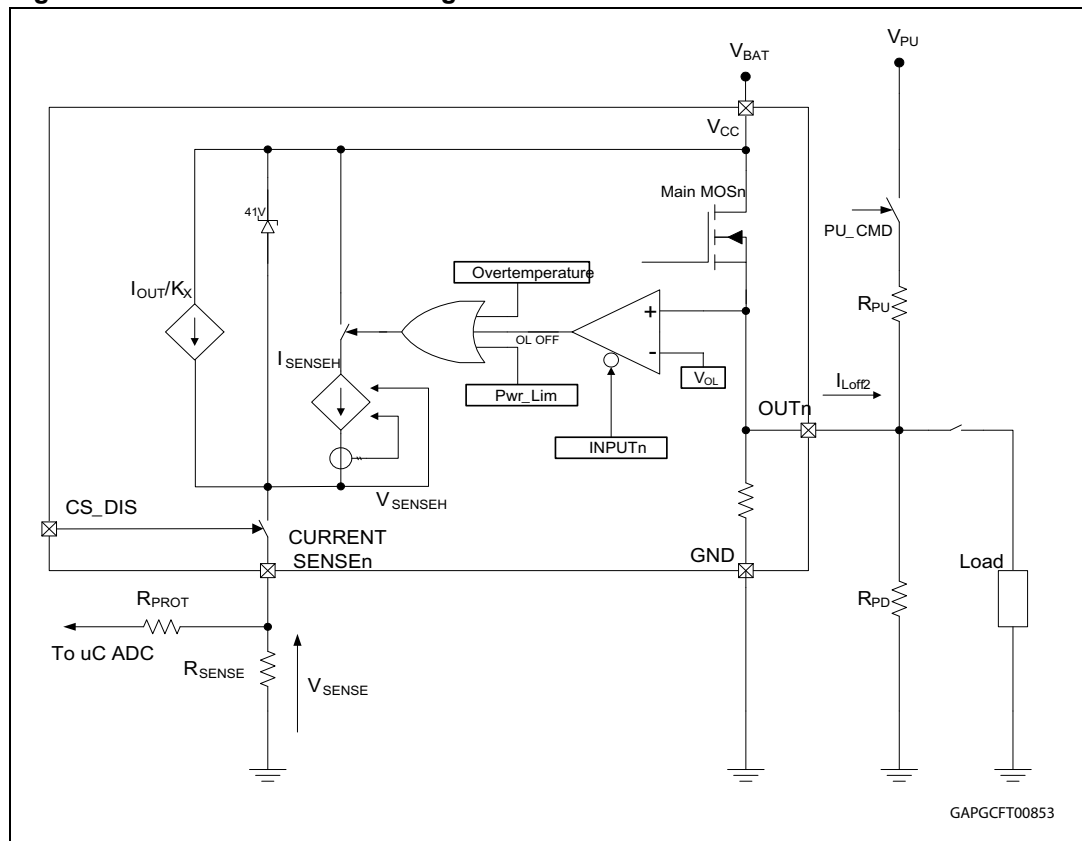
Recommended values:  $R_{prot} = 10 \text{ k}\Omega$ ,  $C_{EXT} = 10 \text{ nF}$

### 3.3 Current sense and diagnostic

The current sense pin performs a double function (see [Figure 32: Current sense and diagnostic](#)):

- **Current mirror of the load current in normal operation**, delivering a current proportional to the load one according to a known ratio  $K_x$ .  
The current  $I_{SENSE}$  can be easily converted to a voltage  $V_{SENSE}$  by means of an external resistor  $R_{SENSE}$ . Linearity between  $I_{OUT}$  and  $V_{SENSE}$  is ensured up to 5 V minimum (see parameter  $V_{SENSE}$  in [Table 7: Current sense \(8 V <  \$V\_{CC}\$  < 18 V\)](#)). The current sense accuracy depends on the output current (refer to current sense electrical characteristics [Table 7: Current sense \(8 V <  \$V\_{CC}\$  < 18 V\)](#)).
- **Diagnostic flag in fault conditions**, delivering a fixed voltage  $V_{SENSEH}$  up to a maximum current  $I_{SENSEH}$  in case of the following fault conditions (refer to [Table 11: Truth table](#)):
  - Power limitation activation
  - Over temperature
  - Short to  $V_{CC}$  in off-state
  - Open-load in off-state with additional external components.

A logic level high on CS\_DIS pin sets at the same time all the current sense pins of the device in a high-impedance state, thus disabling the current monitoring and diagnostic detection. This feature allows multiplexing of the microcontroller analog inputs by sharing of sense resistance and ADC line among different devices.

**Figure 32. Current sense and diagnostic**

### 3.3.1 Short to $V_{CC}$ and off-state open-load detection

#### Short to $V_{CC}$

A short-circuit between  $V_{CC}$  and output is indicated by the relevant current sense pin set to  $V_{SENSEH}$  during the device OFF-state. Small or no current is delivered by the current sense during the ON-state depending on the nature of the short-circuit.

#### Off-state open-load with external circuitry

Detection of an open load in off mode requires an external pull-up resistor  $R_{PU}$  connecting the output to a positive supply voltage  $V_{PU}$ .

It is preferable  $V_{PU}$  to be switched off during the module standby mode in order to avoid the overall standby current consumption to increase in normal conditions, i.e. when load is connected.

An external pull-down resistor  $R_{PD}$  connected between output and GND is mandatory to avoid misdetection in case of floating outputs in off-state (see [Figure 32: Current sense and diagnostic](#)).

$R_{PD}$  must be selected in order to ensure  $V_{OUT} < V_{OLmin}$  unless pulled-up by the external circuitry:

### Equation 2

$$V_{OUT}|_{Pull-up\_OFF} = R_{PD} \cdot I_{L(off2)f} < V_{OLmin} = 2V$$

$R_{PD} \leq 22 \text{ k}\Omega$  is recommended.

For proper open load detection in off-state, the external pull-up resistor must be selected according to the following formula:

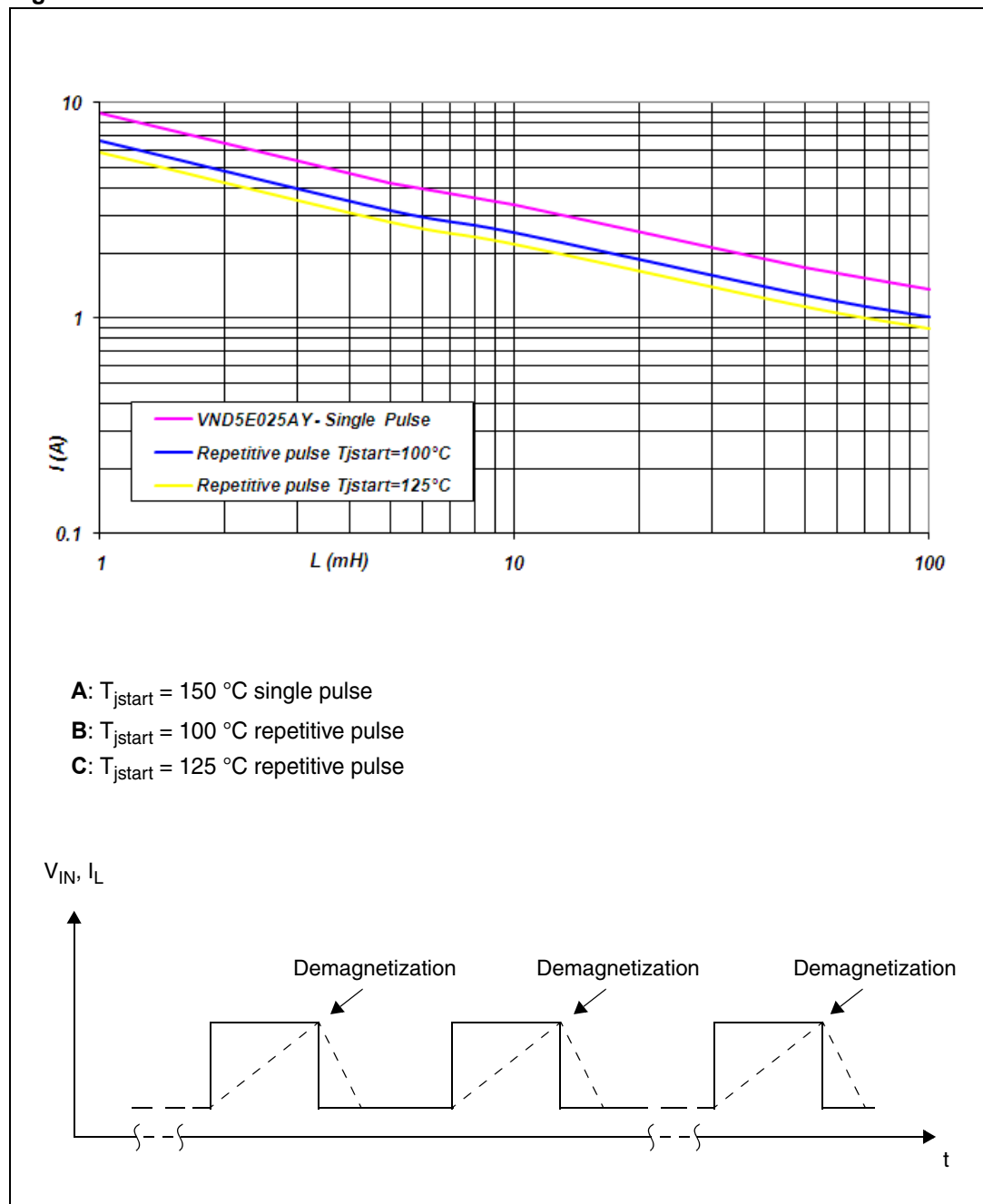
### Equation 3

$$V_{OUT}|_{Pull-up\_ON} = \frac{(R_{PD} \cdot V_{PU}) - (R_{PU} \cdot R_{PD} \cdot I_{L(off2)r})}{(R_{PU} + R_{PD})} > V_{OLmax} = 4V$$

For the values of  $V_{OLmin}$ ,  $V_{OLmax}$ ,  $I_{L(off2)r}$  and  $I_{L(off2)f}$  (see [Table 8: Open-load detection](#) ( $8 \text{ V} < V_{CC} < 18 \text{ V}$ )).

### 3.4 Maximum demagnetization energy ( $V_{CC} = 13.5\text{ V}$ )

Figure 33. Maximum turn off current versus inductance

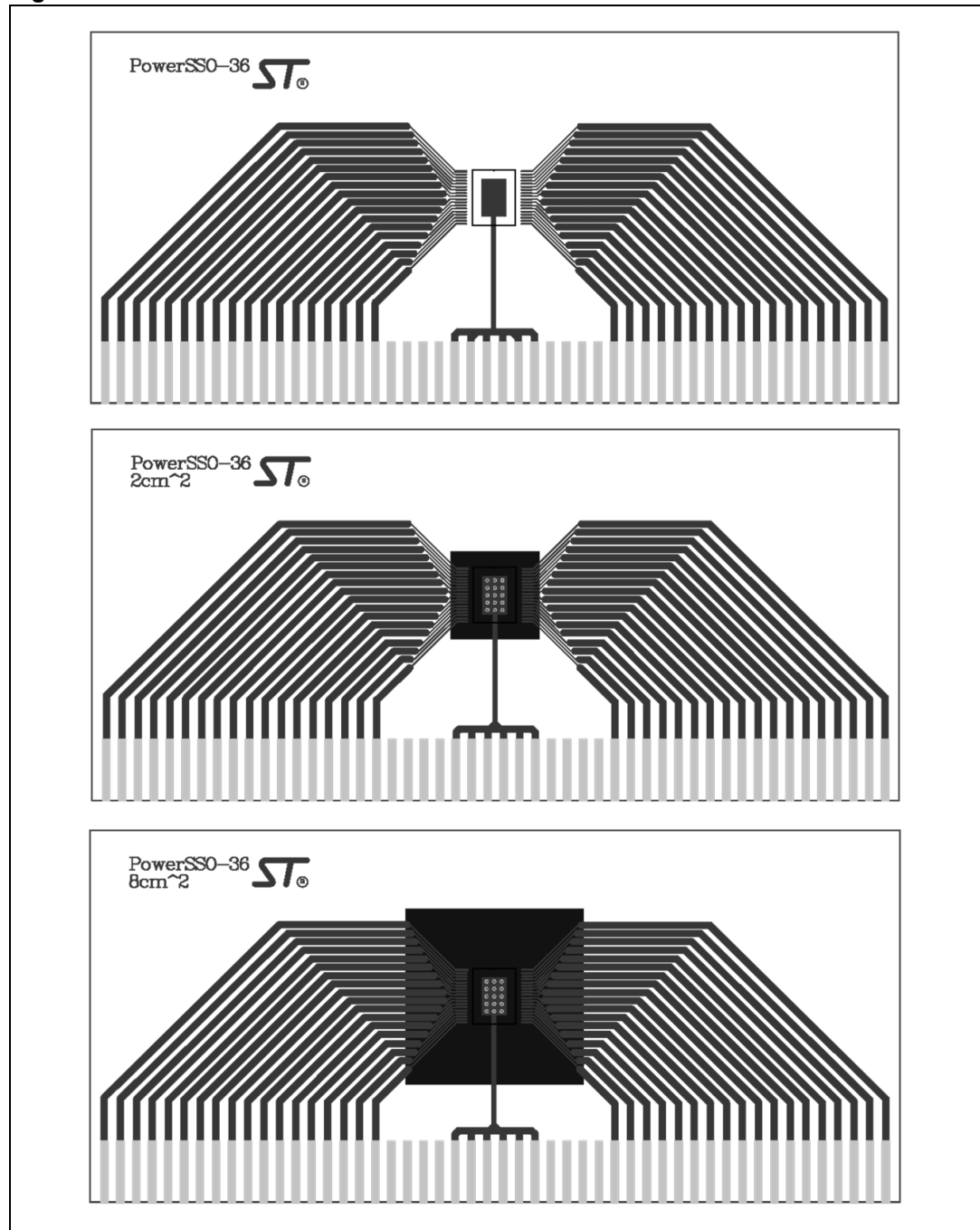


1. Values are generated with  $R_L = 0\ \Omega$ .  
In case of repetitive pulses,  $T_{jstart}$  (at the beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.

## 4 Package and PCB thermal data

### 4.1 PowerSSO-36 thermal data

Figure 34. PowerSSO-36 PC board



1. Layout condition of Rth and Zth measurements (Board finish thickness 1.6 mm +/- 10%; Board double layer; Board dimension 129 mm x 60 mm; Board Material FR4; Cu thickness 0.070 mm; Thermal vias separation 1.2 mm; Thermal via diameter 0.3 mm +/- 0.08 mm; Cu thickness on vias 0.025 mm; Footprint dimension 4.1 mm x 6.5 mm).

Figure 35.  $R_{thj-amb}$  vs PCB copper area in open box free air condition (one channel on)

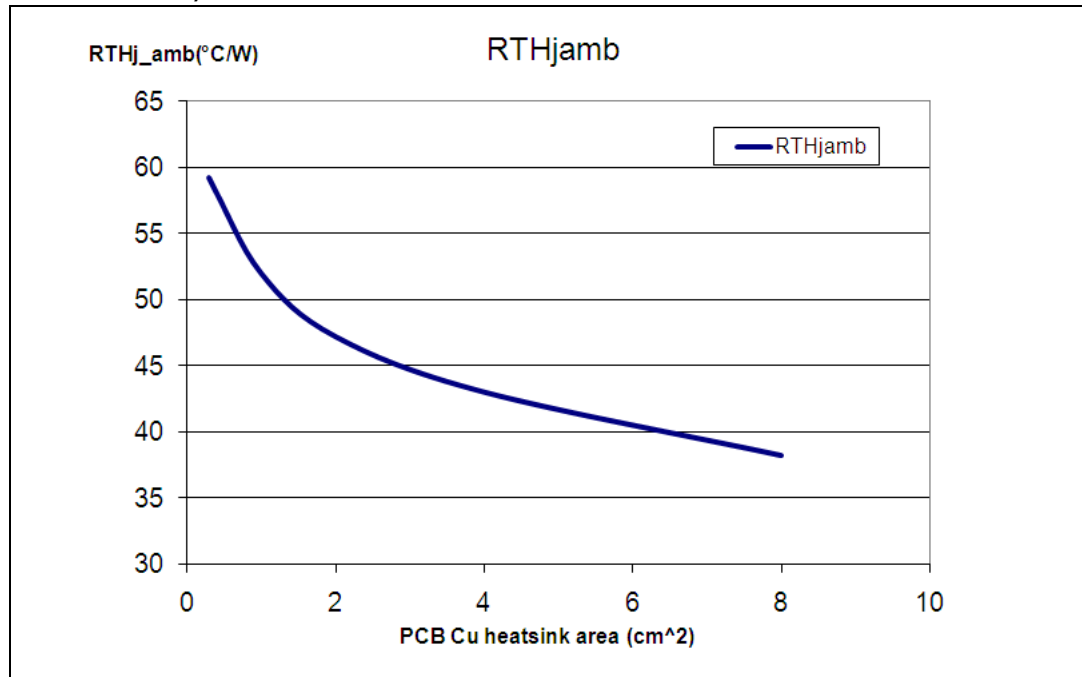
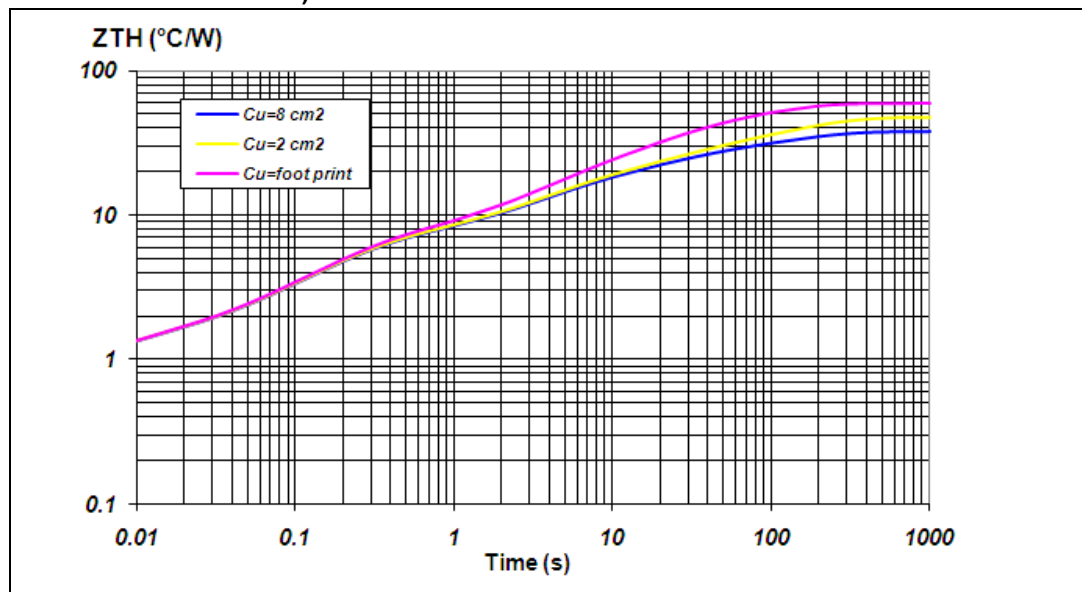


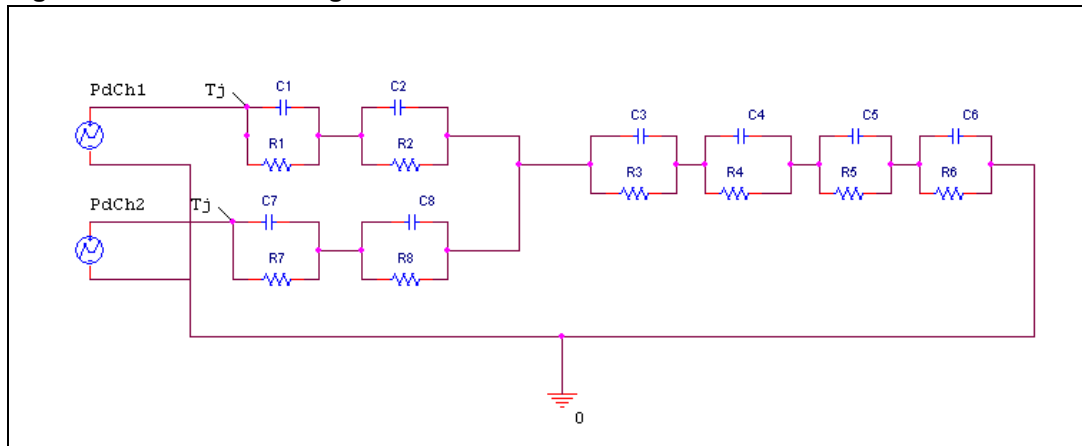
Figure 36. PowerSSO-36 thermal impedance junction ambient single pulse (one channel on)



Equation 4: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where  $\delta = t_p/T$

**Figure 37. Thermal fitting model of a double-channel HSD in PowerSSO-36**

1. The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

**Table 15. Thermal parameters**

| Area/island (cm <sup>2</sup> ) | Footprint | 2  | 8  |
|--------------------------------|-----------|----|----|
| R1 = R7 (°C/W)                 | 0.3       |    |    |
| R2 = R8 (°C/W)                 | 0.9       |    |    |
| R3 (°C/W)                      | 5         |    |    |
| R4 (°C/W)                      | 8         |    |    |
| R5 (°C/W)                      | 18        | 10 | 10 |
| R6 (°C/W)                      | 27        | 23 | 14 |
| C1 = C7 (W.s/°C)               | 0.001     |    |    |
| C2 = C8 (W.s/°C)               | 0.005     |    |    |
| C3 (W.s/°C)                    | 0.04      |    |    |
| C4 (W.s/°C)                    | 0.5       |    |    |
| C5 (W.s/°C)                    | 1         | 2  | 2  |
| C6 (W.s/°C)                    | 3         | 6  | 9  |

## 5 Package information

### 5.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).

ECOPACK® is an ST trademark.

### 5.2 PowerSSO-36 mechanical data

Figure 38. PowerSSO-36 package dimensions

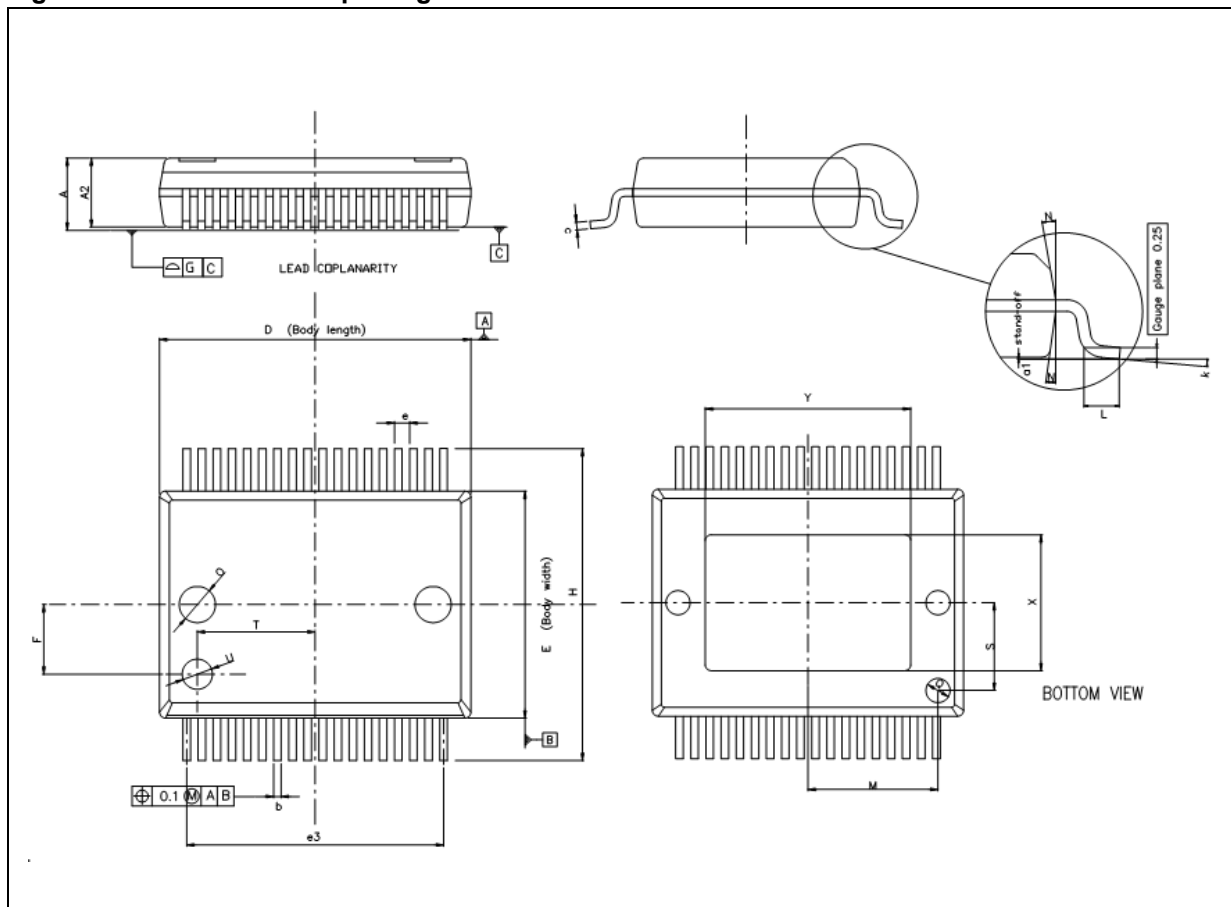




Table 16. PowerSSO-36 mechanical data

| Symbol           | millimeters |      |       |
|------------------|-------------|------|-------|
|                  | Min         | Typ  | Max   |
| A                | 2.15        | -    | 2.45  |
| A2               | 2.15        | -    | 2.35  |
| a1               | 0           | -    | 0.1   |
| b                | 0.18        | -    | 0.36  |
| c                | 0.23        | -    | 0.32  |
| D                | 10.10       | -    | 10.50 |
| E                | 7.4         | -    | 7.6   |
| e                | -           | 0.5  | -     |
| e3               | -           | 8.5  | -     |
| F                | -           | 2.3  | -     |
| G                | -           | -    | 0.1   |
| H                | 10.1        | -    | 10.5  |
| h                | -           | -    | 0.4   |
| k                | 0°          | -    | 8°    |
| L                | 0.55        | -    | 0.85  |
| M                | -           | 4.3  | -     |
| N                | -           | -    | 10°   |
| O                | -           | 1.2  | -     |
| Q                | -           | 0.8  | -     |
| S                | -           | 2.9  | -     |
| T                | -           | 3.65 | -     |
| U                | -           | 1.0  | -     |
| X <sup>(1)</sup> | 4.3         | -    | 5.2   |
| Y <sup>(1)</sup> | 6.9         | -    | 7.5   |

1. Corresponding to internal variation C.

## 5.3 Packing information

Figure 39. PowerSSO-36 tube shipment (no suffix)

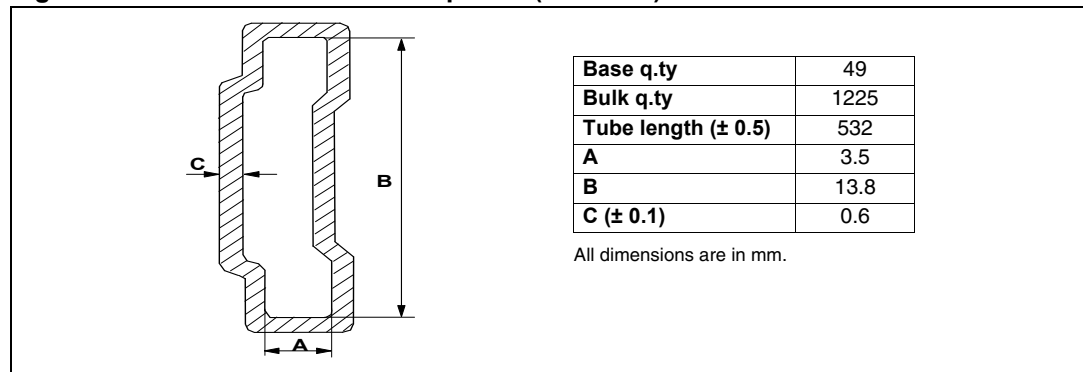
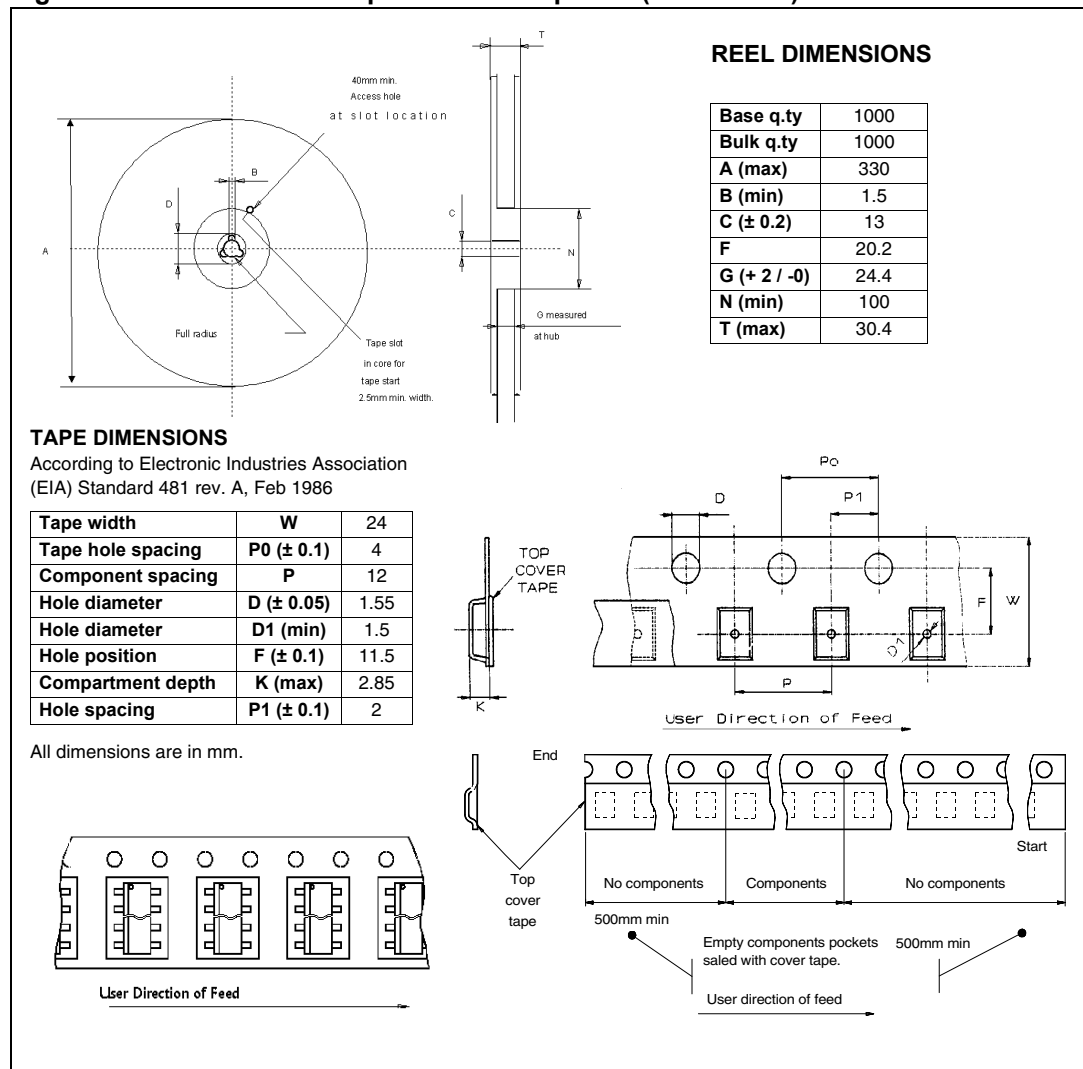


Figure 40. PowerSSO-36 tape and reel shipment (suffix "TR")



## 6 Device summary

Table 17. Device summary

| Package     | Order codes  |                |
|-------------|--------------|----------------|
|             | Tube         | Tape and reel  |
| PowerSSO-36 | VND5E025AY-E | VND5E025AYTR-E |

## 7 Revision history

**Table 18. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                          |
|-------------|----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 29-Jul-2010 | 1        | Initial release.                                                                                                                                                                                                                                                                                 |
| 05-Aug-2010 | 2        | Updated following figures:<br>– <i>Figure 35: <math>R_{thj-amb}</math> vs PCB copper area in open box free air condition (one channel on)</i><br>– <i>Figure 36: PowerSSO-36 thermal impedance junction ambient single pulse (one channel on)</i><br>Updated <i>Table 15: Thermal parameters</i> |
| 19-Jul-2012 | 3        | Changed document status from “Preliminary data“ to “Production data“                                                                                                                                                                                                                             |
| 19-Sep-2013 | 4        | Updated Disclaimer                                                                                                                                                                                                                                                                               |

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